INSTRUCTION MANUAL FT-221 R

YAESU MUSEN CO., LTD.

TOKYO JAPAN

TABLE OF CONTENTS

	(Page)
GENERAL DESCRIPTION	1
SPECIFICATION	2
INSTALLATION	4
CONTROLS AND SWITCHES	6
REAR PANEL CONNECTIONS	8
OPERATION	9
BLOCK DIAGRAM	13
CIRCUIT DESCRIPTION	14
ALIGNMENT AND MAINTENANCE	25
RESISTANCE VOLTAGE CHART	32
PARTS LIST	38

FT-221R VHF TRANSCEIVER



GENERAL DESCRIPTION

The model FT-221R two meter transceiver is a precision built, compact, high performance transceiver of advanced design, providing all mode operation: SSB (LSB or USB selectable), AM, CW and FM with repeater offset capability. Advanced PLL (Phase-Lock Loop) circuitry offers unsurpassed stability and clean, spurious free signals. The transceiver operates at an input of 20 watts on 144 through 148 MHz, in eight 500 kHz segments permitting 1 kHz accurate dial readout. All circuits are fully transistorized and computor type plug-in modules are used for increased reliability and service ability.

Adoption of pre-set passband tuning and wide band amplifier techniques, provide the optimum selectivity and performance needed on today's active 2 meter band.

The transceiver is self contained, requiring only an antenna and power source for home, portable or mobile operation. The transceiver may be operated from 100/110/117/200/220 or 234 volt AC when the power transformer is appropriately wired. The FT-221 is normally supplied for 117 volt AC and 12 volt DC operation. Two power cords are

supplied with the transceiver. Selection of AC or DC operation is automatically made when the proper line cord plug is inserted into the receptacle on the rear panel.

Deluxe features such as VOX, break-in CW with side tone, 100 kHz calibrator, noise blanker and squelch are built-in. In addition to continuous VFO coverage, 88 crystal-controlled channels (11 channels x 8 bands = 88 channels), clarifier and speaker are all integral parts of the unit. For "tone burst" actuated repeater operation, an adjustable "tone burst" generator with automatic tone actuation circuit (patent pending) is included.

The entire transceiver weighs approximately 8.5 kg, and is 280 m/m wide, 125 m/m high, and 295 m/m deep. Construction of heavy-gage steel provides an extremely rugged package, virtually immune to the effects of vibration and shock encountered in rugged mobile service.

SPECIFICATIONS

GENERAL

Frequency Range: 144.0 ~ 144.5 MHz 144.5 ~ 145.0 MHz 145.0 ~ 145.5 MHz 145.5 ~ 146.0 MHz 146.0 ~ 146.5 MHz 146.5 ~ 147.0 MHz 147.0 ~ 147.5 MHz 147.5 ~ 148.0 MHz Frequency Readout: Better than 1 kHz

Emission:

SSB (LSB or USB selectable), AM, FM and CW.

Power Output:

SSB	12 Watts PEP
FM, CW	14 Watts
AM	2.5 Watts

Frequency Stability:

Within 100 Hz during any 30 minute period after warm up. Not more than 20 Hz with a 10% line voltage variation.

Antenna Impedance: 50 ohms unbalanced

Repeater Burst Signal: 1500 to 2000 Hz adjustable

Repeater Split 600 kHz and any frequency up to 1 MHz

Power Requirement:

AC 100/110/117/200/220/234 volts 50/60 Hz DC +12 ~ 14.5 Volts, negative ground

Power Consumption:

- AC Receive 30VA Transmit 90VA at 10 watts output
- DC Receive 0.6A Transmit 3A at 10 watts output

Size:

280 (W) x 125 (H) x 295 (D) m/m

Weight: Approx. 8.5 kg

RECEIVER

 Sensitivity:
 SSB/CW
 0.5 μV for 10 dB S/N

 FM
 0.75 μV for 20 dB QS

 AM
 1.0 μV for 10 dB S/N

Selectivity:

SSB/CW/AM FM (US Model) (European Model)

2.4 kHz at 6 dB 4.1 kHz at 60 dB ±6 kHz at 6 dB ±12 kHz at 60 dB ±8 kHz at 6 dB ±16 kHz at 60 dB

Image Ratio: Better than - 60 dB

Spurious Response: Better than $1 \mu V$ at antenna input

Speaker Impedance: 4 ohms

Audio Output: 2 Watts at 10% distortion

TRANSMITTER

Audio Response: $300 \sim 2700 \text{ Hz} \pm 3 \text{ dB}$

Carrier Suppression: 40 dB or better

Unwanted Sideband Suppression: 40 dB or better at 1 kHz

Spurious Radiation: Down 60 dB or better

FM Deviation: Maximum 12 kHz: Factory set at ±5 kHz

SEMICONDUCTOR COMPLEMENT

Transistors:				Programmable Un	ijunction	Transistor:	
2SD114	1	2SC735Y	3	N13T1	1		
2SD313D	3	2SC711	1				
2SC372Y	34	2SA695	1	Diodes:			
2SC784R	5	2SD359	1	DS-130YD	1	WZ-110	1
2SC373	3	2SB529	1	1S1555	57	1N4740	1
MPSA13	1	2SC1000GR	2	10D1	7	GD-1	1
2SC741	1	BAM-20	1	M4B-5	1	RD-1	1
2SC730	1	BAM-40	1	1S188FM	13	TLR-108	1
				1S1007	12	1SV50	3
FETs:				1S330	1	1S2209	12
2SK19GR	15	3SK51	1	WZ-061	2	1S2687	1
2SK19Y	2			WZ-090	1		
Integrated Circuits				Thyristor:			
μA703HC	2	TP4011AN	4	CW-01B	1		
LD3001	2	SN7490	1	CH OID			
TA7061AP	1	TA7045M	1	Varistor:			
TP4049AN	1	TP4027AN	1	MV-5W	1		

The FT-221R is supplied complete with all cables, connectors, fuses and microphone as shown below.



Figure 1

GENERAL

The FT-221R transceiver has been designed primarily for base service, requiring only an antenna. However, the transceiver provides for efficient mobile service. The transceiver has been factory pre-tuned and requires no adjustment for normal operation into a matched 50 ohm load.

The antenna and its location are the most important consideration in both base and mobile installations, where effective communication range is directly related to antenna height. The antenna should always be as high and in the clear as possible, and a minimum distance of 5 feet should be maintained between the VHF and other antennas. In a mobile installation, it is advisable to locate the antenna as far from the engine as practical in order to minimize any ignition noise pickup. In all installations, the most popular antenna types are either a 1/4 wave length whip with unity gain or a 5/8 wave length whip with a base matching device affording approximately 3.5 dB gain. Our mobile antenna, RSL-145, is available through your dealer.

To minimize loss in the antenna system, use the shortest length of coaxial cable that is practical, avoiding any sharp angles or kinks. Use type RG-8/U cable if the transmission line length exceeds 25 feet, while RG-58/U may be used for shorter lengths.

BASE STATION INSTALLATION

The transceiver is designed for use in many areas of the world where the supply voltage may differ from the operator's local supply voltage. Therefore, before connecting the AC cord to the power outlet, be sure that the voltage marked on the rear of the transceiver agrees with the local AC supply voltage. If not, please refer to Page 5 for rewiring of the transformer primary connections.

CAUTION

PERMANENT DAMAGE WILL RESULT IF IM-PROPER AC SUPPLY VOLTAGE IS APPLIED TO THE TRANSCEIVER. OUR WARRANTY DOES NOT COVER THE DAMAGE CAUSED BY SUCH AN IMPROPER SUPPLY VOLTAGE. Be sure that a proper fuse is used according to the local supply voltage: 2 amps for 117 volts and 1 amp for 220 volts. The transceiver should be connected to a good ground. The ground lead should be connected to the terminal marked GND located on the rear panel of the transceiver.

It is recommended that excessively warm locations be avoided. The transceiver should be placed in a location that has adequate space to permit free air circulation through the cabinet openings.

MOBILE INSTALLATION

The transceiver will operate satisfactorily from any 12 volt negative ground battery source by connecting the DC power cord to the rear panel receptacle. In the car, a location should be selected that is clear of heater ducts to protect it from excessive heat. No special mounting precautions need to be observed if adequate ventilation space is available. A minimum of two inches air space above the cabinet top and on all sides is recommended to allow proper air flow around the cabinet. You may put it on the seat but be sure that there is clearance between the transceiver bottom and seat. Since the transceiver requires an average of 3 amps on transmit, the fuse in the DC power cable should be rated at 5 amps.

When making connections to the car battery, be certain that the RED lead is connected to the positive (+) terminal and the BLACK lead to the negative (-) terminal of the battery. Reversed connection could permanently damage the transceiver. The BLACK lead should run directly to the negative terminal of the battery. The power cable should be kept away from ignition wires and be as short as possible to minimize voltage drop and to provide a low impedance path from the transceiver to the battery.

Prior to operating the transceiver in a mobile installation, the voltage regulator setting should be checked. In many vehicles, the voltage regulators are very poor and in some cases the regulator may be adjusted for an excessively high charging voltage. As the battery and regulator age, the maximum voltage while charging can increase to a very high level which is not only detrimental to the battery but could cause damage to the transceiver.

The transceiver is designed to operate from a source voltage range of 11 to 14 volts. It is necessary to carefully set the regulator so that the highest charging voltage does not exceed 14 volts. The transceiver should be switched "OFF" when the vehicle is started in order to prevent voltage transients from damaging the transistors.

It is recommended that the microphone furnished with this transceiver be used, however any other microphone of $500 \sim 600$ ohm impedance may be used. Refer to Figure 2 for the microphone plug connections. The microphone bracket may be put on the side of the cabinet. It may also be put at any convenient place by making two 2.5 m/m holes spaced 14 m/m.

A speaker is built into the transceiver, however the audio output is also available for an external speaker use. Any speaker having a 4 ohm impedance may be used and when the external speaker plug is plugged into the EXT SP jack on the rear panel, the built-in speaker is disabled.







Figure 3: Transformer Primary Wiring

CONTROLS AND SWITCHES

The transceiver has been specifically designed for flexible operation and versatility. All internal controls have been preset at factory. Several of the controls are unusual in operation, and improper adjustment may result in poor quality signals. The

various front panel controls and their functions are described in the following section. Be certain that you thoroughly understand the function of each control before operating the transceiver.



Figure 4 : Front Panel Controls & Switches

(1) MAIN TUNING control

The tuning knob, located below the dial window, determines the actual frequency of operation in combination with the BAND switch. A dual rate, concentric dial drive system is employed for a coarse and fine setting of the operating frequency.

(2) BAND switch

The BAND switch is an eight-position switch that selects one of the 500 kHz segments in two meter amateur band.

These segments are:

144.0	:	144.0 ~ 144.5 MHz
144.5	:	144.5 ~ 145.0 MHz
145.0	:	145.0 ~ 145.5 MHz
145.5	:	145.5 ~ 146.0 MHz
146.0	:	146.0 ~ 146.5 MHz
146.5	:	146.5 ~ 147.0 MHz
147.0	:	147.0 ~ 147.5 MHz
147.5	:	147.5 ~ 148.0 MHz

(3) CHANNEL switch

The CHANNEL switch selects one of 11 crystals for crystal controlled operation. This switch also selects the VFO for continuous tuning with the main tuning knob.

(4) MODE switch

The MODE switch is a five-position switch. This switch selects the mode of operation: LSB (lower side band SSB), USB, (upper side band SSB), CW (code operation), AM (amplitude modulation) and FM (frequency modulation).

(5) CLARIFIER control

The CLARIFIER control provides a means of OFF setting the receiver frequency approximately 4 kHz to either side of the transmitting frequency. Thus it is possible to set the pitch of the voice or signal you are receiving to the most readable point without affecting your transmitting frequency. Its

- 6 -

use is particularly valuable in "net" operation when several participants may be transmitting slightly off frequency. The CLARIFIER control may be switched off with CLARIFIER switch and the receiver locked to the transmitting frequency. Normally you will want to keep the CLARIFIER in the OFF position until the initial contact is made. The CLARIFIER switch may also be used to change both transmitting and receiving frequencies simultaneously when the CLARIFIER switch is put in the TX-RX position.

(6) CALIB.

When depressed, this button locks the 1 kHz dial for dial calibration.

(7) MIC GAIN control

The MIC GAIN control varies the audio level from the microphone amplifier stages. The control has sufficient range to permit the use of any 600 ohm dynamic microphone.

(8) RF GAIN control

The RF GAIN control varies the gain of the receiver RF and IF amplifiers. Maximum sensitivity is obtained when the control is set to the fully clockwise position.

(9) AF GAIN control & switch

The AF GAIN control adjusts the audio output level to the speaker and phone jack. Clockwise rotation increases the audio output. When the knob is pulled out, the noise blanker is activated in order to minimize pulse type noises.

(10) SQUELCH control

This control adjusts the receiver squelch threshold level.

(11) VOX GAIN control & switch

This controls the VOX gain and functions for push to talk, stand-by or manual operation.

(12) POWER switch

The POWER switch turns transceiver "ON" and "OFF" for both AC and DC operation.

(13) FUNCTION switches

RPT

This switch is used for repeater operation.

In the NOR (normal) position, the transmitter frequency shifts 600 kHz down and in the REV (reverse) position, the receiver frequency shifts 600 kHz up.

AUX/600 kHz

Selects the repeater shift frequency. In the 600 kHz position, the TX or RX frequency shifts 600 kHz with the REPEATER switch ON. Any split within 1 MHz can be installed as option. Refer to Repeater Operation paragraph on Page 12.

DISC

This switch selects the meter to read discriminator center current for FM reception.

MARK

100 kHz calibrator switch.

CLAR

Clarifier switch. Turns the CLARIFIER on in upper position, and off in middle position. In the TX-RX position, the CLARIFIER works for both transmit and receive.

(14) PHONE jack

Phone jack for an external headphones or speaker. The internal speaker is disconnected when the headphone plug is inserted.

(15) MIC jack

The microphone supplied is the recommended one for use with the transceiver, however any microphone having a 500 to 600 ohm impedance may be used.

(16) **DIAL**

Dial window for frequency readout. The coarse scale indicates 100 kHz increments and fine scale indicates 1 kHz increments.

(17) METER

The meter indicates signal strength, FM discriminator center current in receive and relative power output in transmit.

(18) CLAR lamp

This lamp lights when the CLARIFIER is in use.

(19) RPT lamp

This lamp lights when the repeater switch is ON.

REAR PANEL CONNECTIONS



Figure 5 : Rear Panel Connections

(1) ANT

Coaxial connector for an antenna.

(2) GND

Ground connection.

(3) ALC

ALC (automatic level control) input.

(4) RL

Relay contacts for the control of external equipment.

(5) SP jack

External speaker audio output.

(6) KEY jack

Key jack for code operation.

(7) TONE-IN

Tone-pad input jack.

(8) **FUSE**

Fuse holder. For AC operation, a 2 amp fuse is used on 100/117 volts and, a 1 amp fuse on 200/234 volts.

(9) POWER receptacle

Both AC and DC cables are supplied with the transceiver.



- 8 -

The tuning procedure of the transceiver is not complicated, however care should be exercised when tuning to insure peak performance of the equipment. The following paragraphs describe the procedure for receiver and transmitter tuning.

INITIAL CHECK

Before connecting the transceiver to a power source, carefully examine the unit for any visible damage. Check that all modules and crystals are firmly in place and that controls and switches are operating normally. Ensure that voltage specification marked on the rear panel matches the supply voltage.

DIAL READOUT

The main tuning dial is color coded with the band selector switch for proper frequency readout. When the band selected is marked in white on the transceiver front panel, the operator reads the white scale on the main tuning drum. When the band selected is marked in amber the operator reads the amber scale. The main tuning drum is marked in 50 kHz increments. This provides a coarse frequency setting within the band. The round subdial on the dial window surrounding the tuning knob is scaled in 1 kHz increments and provides fine settings of the transceiver operating frequency. The following example will familiarize yourself with the relationship of main and subdial frequency readout.



Read the white scale on main dial for the bands 144.0, 145.0, 146.0 and 147.0, and amber scale for 144.5, 145.5, 146.5 and 147.5.

Then the setting shown in the example would be 144.480 MHz on 144.0 BAND switch setting, and 145.480 MHz on 145.0. And also the frequency would be 144.980 MHz on 144.5 BAND switch setting, and 145.980 MHz on 145.5.

RECEIVER

After the transceiver is properly set up for operation, set the controls and switches as follows;

POWER ····· Down to "OFF" position.
MODE Desired mode.
BANDDesired band.
RPT Lever position horizontal
to OFF position.
AUX-600 kHz Lever position horizontal
to 600 kHz shift
DISC······Lever position horizontal
to OFF position.
MARK Lever position horizontal
to OFF position.
CALR Lever position horizontal
to OFF position.
NOR-REV···································
MAIN TUNING DIAL · · Desired operating fre-
quency.
VOX GAIN·····PTT.
AF GAIN ····· Desired audio level.
RF GAIN ······Fully clockwise position.
CHANNEL · · · · · · · · · VFO.
SQUELCH ······Fully counter-clockwise
position.

Connect the cord supplied to the appropriate power source, and an antenna to antenna connector on the rear panel.

CAUTION

PERMANENT DAMAGE WILL RESULT IF IM-PROPER SUPPLY VOLTAGE IS APPLIED TO THE TRANSCEIVER. WARRANTY DOES NOT COVER THE DAMAGE CAUSED BY IMPROPER SUPPLY VOLTAGE.

Figure 7

Turn on the POWER switch. The dial and meter lamps should light up, and the transceiver is now ready to operate.

(1) SSB and AM Modes

Using the main tuning control (VFO), tune in an incoming signal. USB (upper side band) is mostly used for 2 meter SSB operation. When the received signal can not be heard clearly, then change to the opposite side band. The RF GAIN control is normally set to the fully clockwise position, but if the incoming signal is extremely strong, it is recommended to turn this control back to prevent overload of the front end. When there is noise caused by automobiles, pull the AF GAIN control out to switch on the NB (noise blanker) in order to eliminate these pulse type noises.

(2) CW Mode

With the CLARIFIER switch in the OFF position, tune in a signal until an 800 Hz beat tone is heard. Under this condition, your transmitting frequency coincides with the received signal. If you desire to hear a beat tone of your choice, then use the CLARIFIER control.

(3) FM Mode

Using the tuning control, tune in an incoming signal for a maximum and steady S-Meter reading where a natural voice is heard. For accurate tuning, set the DISC switch to the upper ON position. Carefully readjust the tuning control until the meter indicates zero (half way of the full scale).

If the S-Meter indication wabbles or if a clean audio output is not available, it is very likely that the signal is in the SSB mode. In this case, turn the MODE switch to USB or LSB position, and carefully tune the tuning control until a clear voice is heard. It is important that the CLARIFIER switch be set to the OFF position when calling the another station. After the initial contact is made, then the CLARIFIER may be used for the desired listening sound.

FREQUENCY CALIBRATION

(1) SSB Mode

Set the CLARIFIER to the OFF position, and the tuning control to the 100 kHz point on the dial nearest to the desired frequency. Set the MARK switch to the upper position. While pressing the CALIB knob to lock the dial, tune the tuning control for a zero beat. The transceiver must be recalibrated when changing the mode of operation: USB, LSB, AM or CW.

(2) FM Mode

Set the CLARIFIER to the OFF position, and the tuning control to the 100 kHz point in the round dial nearest to the desired operating frequency. Set the MARK switch and DISC switch to ON position. While pressing the CALIB knob down to lock the dial, tune the main tuning control until the meter indicates the green portion of its scale.

NOTE: WHEN THE MARKER SWITCH IS IN THE "ON" POSITION, THE ANTENNA IS DISCONNECTED FOR EASIER CALIBRATION.

TRANSMITTER

Connect a 50 ohm dummy load or a matched antenna to the coaxial fitting on the rear panel. Since the transmitter section utilizes wide band techniques no tuning control is necessary except the main tuning control to select the operating frequency. Plug the microphone into the MIC jack and select the desired mode. Push down the PTT (push-to-talk) switch on the microphone and speak into the microphone.

(1) SSB Mode

The meter indicates maximum deflection on voice peak and zero with no microphone input. Release the PTT switch for receive. Excessive setting of the MIC GAIN will result in poor quality transmitted signals.

(2) AM Mode

When the PTT switch is depressed, the proper amount of carrier is automatically inserted. Adjust the MIC GAIN control until the meter indicates a very slight movement with voice peaks while speaking into the microphone normally.

(3) CW Mode

Plug the key into the KEY jack on the rear panel. In the key down condition, the meter will show a 6 to 8 relative power output, and with the key up, the receiver will recover. The break-in delay time may be adjusted with VR_{601} , under the top cover.

(4) FM Mode

Set the MIC GAIN control to the 12 o'clock position and push the PTT switch on the microphone while speaking normally into the microphone. The meter will show a 6 to 8 relative power output. Release the PTT switch on the microphone for receive.

(5) VOX (Voice Controlled) Operation

Adjust the VOX GAIN control on the front panel until your voice actuates the transmitter while speaking normally into the microphone. Set the ANTITRIP control to the minimum point in order to prevent the speaker output from tripping the VOX circuit. Do not use more VOX GAIN or ANTITRIP GAIN than necessary. Adjust the DELAY control for a suitable release time. The RELAY control provides coarse adjustment for relay sensitivity and this control has been preset at factory. These controls are located on the AF AMP UNIT under the top cover.

REPEATER OPERATION

Transmitting and receiving frequencies may be shifted 600 kHz for repeater operation. When the REPEATER switch is ON (upward position) with NOR-REV switch in the NOR (normal) position, the transmitted frequency is shifted 600 kHz down from the dial readout. With the NOR-REV switch at REV position, the received frequency is shifted 600 kHz down from the dial readout. The U.S. model has an automatic cross-over system in which this shift is automatically reversed from 147.0 to 148.0 MHz.

In NOR operation, the transmitting frequency is shifted 600 kHz down for the frequency range of 146.61 through 146.97 MHz and shifted 600 kHz up for the frequency range of 147.00 through 147.39. This is shown on the chart on Figure 8. These relations are reversed with the NOR-REV switch in the REV position. Extreme caution should be observed so as not to transmit outside



Repeater Frequency Chart for U.S. Model

Figure 8

-11 -

the amateur bands with repeater switch ON. The most repeaters use 600 kHz split between transmitter and receiver frequencies, however, other split than 600 kHz has been adopted in some areas.

When the AUX/600 kHz switch is in the AUX position, the frequency is shifted to any frequency within 1 MHz determined by the optional crystal installed in the local unit. The RPT lamp lights up when the repeater switch is ON.

Tone actuated repeaters can be operated with the built-in tone burst signal which is automatically inserted by the push-to-talk switch at the start of a transmission. When the microphone PTT switch is depressed for 0.2 - 0.5 seconds before the voice transmission, the burst tone signal is inserted at the beginning of the transmission. Normal operation of the PTT switch does not generate the burst signal. The frequency of the burst signal may be adjusted from 1500 to 2000 Hz with VR₁₀₀₂ under the top cover.

AUX crystal specification is calculated as follows: BAND 146.5 ; X MHz =

 $(127.8 - \text{shift frequency}) \div 9$ BAND 147.0 ; X MHz = $(128.3 + \text{shift frequency}) \div 9$

Example 1

Calculate crystal frequency for -800 kHz shift in 146.5 MHz segment. (TX frequency 800 kHz lower)

 $X MHz = (127.8 - 0.8) \div 9 = 14.111 MHz$

Example 2 Calculate crystal frequency for +800 kHz shift in 147.0 MHz segment. (TX frequency 800 kHz higher) X MHz = (128.3 + 0.8) ÷ 9 = 14.344 MHz

CRYSTAL CONTROLLED OPERATION

In addition to the normal VFO controlled operation, eleven crystals may be selected by the channel switch on the front panel for crystal controlled operation. This crystal controlled operation is of great advantage when the transceiver is operated on the preset frequencies. Since the entire 2 meter band has been split into eight bands, eleven crystals can be used as 88 crystal controlled channels. The crystal holders accept standard, HC-25/U type crystals. All crystal frequencies must fall between 8,000 kHz and 8,500 kHz. A trimmer capacitor has been connected in series with each crystal to permit proper frequency adjustment. Adjustment of this trimmer will change the crystal frequency approximately 1 kHz. The correct crystal frequency cy for any desired operating frequency may be determined by using the following formula:

 $fx = fo - f_1$

where fx : crystal frequency

fo : operating frequency

 f_1 : given from Table 1

BAND (MHz)	LSB (kHz)	USB (kHz)	FM (MHz)
144.0-144.5	136001.5	135998.5	136.0
144.5-145.0	136501.5	136498.5	136.5
145.0-145.5	137001.5	136998.5	137.0
145.5-146.0	137501.5	137498.5	137.5
146.0-146.5	138001.5	137998.5	138.0
146.5-147.0	138501.5	138498.5	138.5
147.0-147.5	139001.5	138998.5	139.0
147.5-148.0	139501.5	139498.5	139.5

Table 1

Example (1) – Find the proper crystal frequency for 144.15 MHz USB operation

From the Table 1, f_1 for USB is 135998.5. Therefore, fx = 144.15 - 135.9985 = 8151.5 kHz

Example (2)- 144.72 MHz FM operation

fx = 144.72 - 136.5 = 8220 kHz



FT-22IR BLOCK DIAGRAM

GENERAL

The block diagram and the circuit description that follows with provide you will a better understanding of this transceiver. Computor type plug-in modules have been adoped throughout the transceiver.

The transceiver consists of a single conversion receiver with a 10.7 MHz IF for SSB, CW and AM, a double conversion receiver with a 10.7 MHz first IF and 455 kHz second IF for FM. A single conversion transmitter, utilizing a 10.7 MHz high frequency crystal filter for SSB generation and varactor diode frequency modulation on 10.7 MHz crystal oscillator is incorporated.

NOTE:

The parts number starts with the number shown below the printed board designation. For example, the field effect transistor 3SK51 in RX RF unit PB-1456 is Q_{401} .

RECEIVER

RX RF UNIT (PB-1456)

The 144 MHz input signal from the antenna is fed through the antenna relay, RL_{1201} , to pin 5 of the RX RF unit. The signal is amplified by the RF amplifier Q_{401} , **3SK51** field effect transistor, and then fed to the gate of the first mixer Q_{402} , **2SK19GR**, where the input signal is heterodyned with a 133.3 MHz to 137.3 MHz signal, delivered

from phase-lock-loop unit, and thus produces an IF signal of 10.7 MHz at the drain circuit of Q_{402} .

The input and output circuits of the RF amplifier utilize a double tuned circuit, which is sharply tuned to the center of the band with the varactor diodes, D_{401} through D_{404} , thus eliminating cross modulation and intermodulation effects.

The IF signal passes through crystal filter XF401, FMT-30, and the SSB, AM and CW signal is then fed to the first IF amplifier Q_{404} , 2SC372Y, while the FM signal is fed to Q_{403} , 2SC372Y.

The SSB, AM and CW signal amplified by Q_{404} is fed through a noise blanker gate diode D_{407} , **1S1007**, to pin 14, and the FM signal amplified by Q_{403} is fed to pin 9.

SSB IF UNIT (PB-1462)

The SSB, AM and CW signal from pin 14 of the RX RF unit is fed through pin 3 to the SSB IF unit. The signal is fed through the diode switch and a crystal filter, XF-9, to the IF amplifier Q_{901} , **2SC784R**. The signal is amplified by Q_{901} and Q_{902} , **TA7045M**, and then fed to the ring demodulator consisting of D_{904} through D_{907} , **1S1007**, where a carrier signal is applied through pin 32 from the carrier oscillator in the MIC AMP unit.

The audio output is fed through pin 33 and the MODE switch, S3D, to pin 28 of the same unit. The IF signal is further amplified by Q_{903} , **2SK19GR**, and detected by the AM detector D_{910} , **1S188FM**, for AM mode. Then the audio signal is fed through pin 25 to the MODE switch S3D.

A part of the IF signal output from Q_{903} is rectified by D_{908} , 1S1007, and D_{913} , 1S-1555, for AGC (automatic gain control). The AGC voltage is amplified by Q_{904} and Q_{905} , 2SC373 and controls the gain of IF amplifier Q_{901} and Q_{902} . A part of



it is fed through pin 17 to the RX RF unit to control the gain of the RF amplifier Q_{401} . The AGC voltage is amplified by the S-meter amplifier Q_{905} , 2SC373, and fed to the S-meter through the DISC/SM switch on the front panel.

The audio signal from the MODE switch is preamplified by Q_{907} and Q_{908} , 2SC1000GR and fed through pin 29 to the AF AMP unit.

FM IF UNIT (PB-1463)

The FM IF signal from pin 17 of this unit is fed through a ceramic filter CF_{803} , 10.7 MFBR to the second mixer Q_{805} , 2SC372Y, where the 10.7 MHz signal is mixed with the 10.245 MHz signal generated by the second heterodyne oscillator Q_{809} , 2SC372Y, producing a 455 kHz second IF signal. The 455 kHz IF signal is fed through the ceramic filter, CF_{802} , to the second IF amplifier Q_{806} and Q_{807} , 2SC372Y, and the amplifier limitter Q_{808} , TA7061AP, which removes any amplitude modulation component on the signal. The output from Q_{808} is applied to the discriminator D_{304} and D_{305} , 1S188FM. The discriminator produces an audio output in response to a corresponding frequency (or phase) shift in the 455 kHz IF signal. The discriminator output is then fed to the common audio amplifier stage in SSB IF unit through the MODE switch.

For FM reception, when no carrier is present in the 455 kHz IF, the noise at the discriminator output is fed through the squelch threshold potentiometer, VR₆, to the noise amplifier Q_{810} and Q_{811} , 2SC372Y, and detected by D_{805} and D_{806} , 1S188FM. The DC voltage is applied from pin 8 to the squelch controller Q_{607} , 2SC372Y, in the AF AMP unit.

The 10.7 MHz signal is also applied to the noise blanker amplifier Q_{801} , 2SC372Y. The signal is amplified by Q_{801} , 2SC372Y, and Q_{802} , μ A703HC.





Figure 12

The noise rectifier diodes D_{801} and D_{802} , 1S1555, produce a DC voltage which is amplified by following noise pulse amplifier Q_{803} , 2SK19GR.

Under normal conditions, Q_{803} conducts producing the cut-off voltage to the base of the gate controller Q_{804} , **2SC372Y**, in turn the high collector voltage of Q_{804} is supplied from pin 15 to the gate diode D_{407} , **1S1007**, in the RX RF unit which conducts to pass the signal freely. With pulse noise, Q_{804} conducts and its collector voltage drops causing the gate diode D_{407} to disconnect the IF signal during the noise pulse exists.

AF AMP UNIT (PB-1499)

The audio signal pre-amplified in the SSB IF unit is fed through pin 13 to the audio amplifier stage consisting of Q_{610} , 2SC372Y, Q_{611} , 2SC711, Q_{612} , 2SA695, Q_{613} , 2SD359 and Q_{614} , 2SB529. The audio power amplifier circuit utilizes the OTL (output transformer less) circuitry and delivers 2 watts output to the speaker from pin 8.

In the FM mode, the squelch voltage is applied from pin 12 to the squelch controller Q_{607} , **2SC372Y**, which conducts with noise when the signal is not present, in turn the audio input is grounded to quiet the audio amplifier. When the signal is present, the Q_{607} is cut-off and permits normal operation of the audio amplifier. The DC voltage is also applied from pin 12 to quiet the audio amplifier when the phase lock loop circuit is unlocked.

The speech output from the first microphone amplifier is fed through the VOX GAIN control potentiometer, VR_7 , to the VOX amplifier Q_{601} , 2SC372Y, and Q_{602} , LD-3001, from pin 2.

The amplified signal is fed to the VOX rectifier, D_{601} and D_{602} , 1S1555. The rectified DC voltage is applied to the gate of the VOX relay controllers Q_{603} , 2SK19Y, and Q_{604} , 2SC735Y, causing them to conduct and actuate the VOX relay, RL₁, on the main chassis.

The ANTITRIP circuit provides a threshold voltage to prevent the speaker output from tripping the transceiver into the transmit mode. The receiver audio output voltage is connected through the ANTITRIP potentiometer, VR_{603} , to the antitrip amplifier Q_{605} , 2SC372Y, and fed to rectifiers, D_{603} and D_{604} , 1S1555. The negative DC output voltage from the rectifier is connected to the gate of Q_{603} , and reduces the gain of the VOX control transistor, thus providing the necessary antitrip threshold. The ANTITRIP control, VR₆₀₃, adjusts the value of the antitrip voltage threshold so that the speaker output will not produce an excessive positive voltage from the VOX rectifier that exceeds the negative voltage from the antitrip rectifier causing the controller transistor to actuate the relay. When speaking into the microphone, the



Figure 13

positive voltage will exceed the negative antitrip voltage and actuate the relay. VR_{602} provides coarse adjustment for relay sensitivity.

Relay hold tone will be determined by the DELAY control potentiometer, VR_{601} .

The tone oscillator Q_{606} , 2SC372Y, operates when the MODE switch is in the CW position. It is a phase shift oscillator operating at approximately 800 Hz.

The tone output is activated by the keying circuit through the emitter circuit of Q_{606} and coupled through sidetone level control, VR_{604} , to the receiver audio amplifier, Q_{601} , for sidetone monitoring in CW operation. The output from Q_{606} is also coupled to the VOX amplifier, Q_{602} , for breakin CW operation. In the FM mode, a DC voltage at the discrimination output is applied from pin 17, to the differential amplifier Q_{608} and Q_{609} , **2SK19GR**.

When the frequency of received signal is shifted from the discriminator center, the resulting DC voltage causes either Q_{608} or Q_{609} to conduct indicating the amount of shift on the meter with the DISC switch in the ON position. VR₆₀₅ balances the differential amplifier and VR₆₀₆ calibrates the sensitivity of the meter.

TRANSMITTER

MIC AMP UNIT (PB-1460)

The speech signal from the microphone is fed from pin 31 to the first microphone amplifier, half of Q_{1104} , LD-3001. The input impedance of the microphone amplifier is 600 ohms. This signal is controlled in amplitude by the MIC GAIN control between pins 29 and 31, and is amplified by the second microphone amplifier, the other half of Q_{1104} , and applied to the source follower Q_{1105} , 2SK19GR, to be delivered to the ring modulator D₁₁₀₈ through D₁₁₁₁, 1S-1007.

The carrier oscillator Q_{1108} , 2SC372Y, oscillates at 10.7015 MHz for LSB, 10.6985 MHz for USB and 10.6993 MHz for AM/CW depending upon the MODE switch position. In the CW mode, the carrier oscillator oscillates at 10.6993 MHz for transmit and 10.6985 MHz for receive producing an 800 Hz beat note in the receive mode. In the AM mode, the carrier oscillator does not function while receiving. The MODE switch selects the crystal by means of a diode switch. The output from the oscillator is fed through the buffer amplifier Q_{1107} , 2SC372Y to the balanced ring modulator D_{1108} through D_{1111} , 1S-1007. The



carrier signal output from the buffer amplifier, Q₁₁₀₇, is fed from pin 22 to the SSB IF unit for SSB and CW reception. Carrier balance is obtained with potentiometer, VR₁₀₀₂, and the trimmer capacitor, TC₁₁₀₁. The double side band, suppressed carrier signal is amplified by Q₁₁₀₆, **2SK19GR**, and fed from pin 10 to pin 5 of the SSB IF unit. In the AM and CW modes, the balanced modulator is unbalanced by the DC voltage applied from pin 4 and the carrier signal is fed through T₁₁₀₂ to carrier amplifier Q₁₁₀₁, **2SC372Y**. The amplified carrier is fed from pin 3 to the EXCITER unit.

The audio signal output from Q_{1104} is fed from pin 27 to pin 12 of the EXCITER unit to be amplified to a sufficient level for low level AM modulation.

In the FM mode, a crystal oscillator Q_{1102} , **2SC372Y**, generates a 10.7 MHz signal which is shifted by the varactor diode D_{1102} , **1S2687**, in accordance with the speech voltage. The audio signal from the microphone amplifier, Q_{1104} , is applied to the IDA (instantaneous deviation adjustment) circuit. The IDA circuit, composed of diodes D_{1103} and D_{1104} , **1S188FM**, clips both positive and negative peaks when they exceed a predetermined level in order to limit the maximum deviation of the transmitter.

The limited audio signal is applied through a low pass filter and deviation potentiometer, VR_{1101} , to the audio amplifier Q_{1103} , 2SC372Y, where it is

amplified and applied to the modulator, varactor diode D_{1102} . The low pass filter limits the transmitter modulation spectrum by attenuating the frequencies above the speech range.

The frequency modulated signal is then amplified by Q_{1101} , 2SC372Y, and fed through the output transformer T_{1101} to pin 5 of the EXCITER unit.

When the MODE switch is in the CW position, the emitter circuit of Q_{1107} and Q_{1101} are connected to the key jack through pin 8 and pin 26.

EXCITER UNIT (PB-1466)

The SSB, AM, CW and FM output signal (10.7 MHz) from the MIC AMP unit is fed to the EXCITER unit from pin 3 and pin 5.

The 10.7 MHz signal is fed to the balanced mixer, consisting of Q_{501} and Q_{502} , **2SK19GR**, where the signal is mixed with the 133.3 to 137.3 MHz heterodyne signal delivered from pin 4, producing a 144 to 148 MHz signal. The output signal from the balanced mixer passes through the tuned circuits consisting of L_{501} through L_{504} , which are tuned by the varactor diodes D_{501} through D_{504} , **1S2209**, in which voltages are preset in accordance with the band switch position. Thus the circuit is tuned exactly to the operating frequency com-



Figure 15

pletely reducing any spurious radiation. The signal is then amplified by the amplifier chain Q_{503} , **2SC784R**, Q_{504} , **2SC741**, and Q_{505} , **2SC730**, and delivered from pin 17 to the BOOSTER unit.

The DC voltage for Q_{501} through Q_{504} is supplied through Q_{506} , 2SC735Y. When the phase lock loop circuit is unlocked, the controller transistor Q_{507} , 2SC372Y, stops conducting and in turn Q_{506} stops supplying the DC voltage for Q_{501} through Q_{504} .

The speech signal from pin 27 of the MIC AMP unit is fed through the AM amplifier Q_{508} , 2SC373, and emitter follower Q_{509} , 2SC372Y, to the AM modulator Q_7 , 2SD313D, which controls the supply voltage for Q_{1201} , BAM-20, in the BOOSTER unit.

BOOSTER UNIT (PB-1470)

The signal from EXCITER unit is fed to the BOOSTER unit and amplified by the driver amplifier Q_{1201} , BAM20, and the final amplifier Q_{1202} , BAM-40, which delivers 10 watts of RF power to the antenna through a two stage, low-pass filter. The DC voltage to Q_{1201} is supplied through the AM modulator Q_7 , 2SD313D.

The bias voltage is stabilized at 9 volts by a zener diode D_{1209} , 1N4740. Two diodes D_{1201} and D_{1202} , 10D1, are used to protect the power transistor from damage due to heating by reducing the bias voltage when the temperature rises. A small portion

of the RF output is rectified by a diode D_{1203} , 1S188FM, which delivers a resulting DC voltage to the meter where it provides an indication of relative power output from the transceiver.

The DC voltage obtained from rectifying a small portion of the RF output by the ALC diodes D_{1205} and D_{1206} , **1S1555**, which are biased by the ALC threshold control VR₁₂₀₁, is applied to the gate of Q_{906} in the SSB IF unit and Q_{1106} in the MIC AMP unit. This controls their gain in order to automatically control the driving level to the PA transistors in order to prevent any distortion caused by overdrive.

Block diodes D_{1207} and D_{1208} disconnect the supply voltage to Q_{1202} while the antenna is disconnected for marker calibration.



Figure 16

-19-

OTHER CIRCUITS

Some circuits work for both transmitting and receiving and are described as follows:

PLL CIRCUIT: VFO unit PB-1465 FIX unit PB-1453 LOCAL unit PB-1454 PLL unit PB-1455

The FT-221R utilizes a phase lock loop system for the heterodyne oscillator providing a stable signal varying from 133.3 through 137.3 MHz to cover the entire 2 meter band.

VFO UNIT (PB-1465)

The VFO module board is installed in the VFO chassis. The VFO (variable frequency oscillator) Q_{1301} , 2SC372Y, generates an 8,000 to 8,500 kHz signal and produces a 500 kHz main tuning dial range. Frequency drift is minimized through the use of a temperature compensation circuit utilizing a differential trimmer capacitor. The signal is fed through the amplifier buffer stage Q_{1302} , 2SK19GR, and Q_{1303} , 2SC372Y, to pin 11 of the FIX oscillator board. The buffer amplifier provides isolation and amplification of the VFO signal.







Figure 18

FIX UNIT (PB-1453)

In addition to normal VFO operation, 11 crystals may be selected for crystal controlled operation with the selector switch located on the front panel of the transceiver.

The FIX channel crystal oscillator Q_{101} , 2SC372Y, oscillates at the frequency of the crystal selected by the diode switch D_{101} through D_{111} , 1S1555. The output is fed from pin 8 through the buffer amplifier Q_{102} , 2SC372Y, to the PLL unit.

The signal from the VFO also passes through this buffer stage to the PLL unit.

The crystal frequency falls between 8,000 and 8,500 kHz and is determined as follows.

 $fx = f_0 - f_1$

where f_1 is given in Table 1 on page 12 and f_0 is the operating frequency.

LOCAL UNIT (PB-1454)

This oscillator generates a heterodyne signal which is used to convert the VCO (voltage controlled oscillator) signal to an 8,000 to 8,500 kHz signal, which is used for the comparison of the phase with that of the reference (VFO) signal.

The crystal controlled oscillator Q_{201} , 2SC372Y, oscillates at the fundamental frequency of the crystal. A varactor diode D_{226} , 1SV50, connected to the base of Q_{201} , is used as a clarifier to shift the oscillator frequency for receiver off-set tuning.

The output from the oscillator is fed to the frequency multiplier stage, Q_{202} and Q_{203} , **2SC784R**, producing the ninth harmonic at its output. The crystal is selected by the diode switch connected to the band switch. The relation between the frequency and band is shown on Table 2. The multiplied signal is then fed from pin 3 to the PLL unit.

For repeater operation, a fundamental crystal at 14.1333 MHz, X210, is used to generate a heterodyne signal of 127.2 MHz which is 600 kHz higher than the normal heterodyne signal when the band switch is set to the 146.5 MHz segment and X211 (fundamental frequency 14.3222 MHz) is used to generate 128.3 MHz signal which is 600

kHz higher than the normal heterodyne signal when the band switch is set to the 147.0 segment. A relay, RL_{1001} in the tone burst unit is used to select the above crystals with the Repeater switch, S_8 , in the ON position. When the Normal-Reverse switch, S_9 , is set to the NOR position, the relay selects the repeater crystal on transmit that shifts the transmitting frequency down 600 kHz in the 146.5 MHz segment and shifts up 600 kHz in the 147.0 MHz band. The main VFO tuning dial indicates the received frequency.

With S_9 in the REV position, the relay selects the repeater crystal on receive that shifts the receiver frequency down 600 kHz in the 146.5 MHz segment and shifts up 600 kHz in the 147.0 MHz segment. The main tuning dial now indicates the transmitted frequency.

BAND	Crystal No.	Crystal Frequency	Local Frequency						
144.0	X ₂₀₁	MHz X ₂₀₁ 13.9222							
144.5	X ₂₀₂	13.9777	125.3						
145.0	X203	14.0333	126.3						
145.5	X ₂₀₄	14.0888	126.8						
146.0	X205	14.1444	127.3						
1465	X206	14.2000	127.8						
146.5	X210	*14.1333	127.2						
147.0	X207	14.2555	128.3						
147.0	X ₂₁₁	*14.3222	128.9						
147.5	X208	14.3111	128.8						

*Repeater for US Model.

Table 2



Figure 19

PLL UNIT (PB-1455)

This unit generates a heterodyne signal for the transmitter and receiver mixer in conjunction with the Phase Lock oscillator.

A voltage controlled oscillator Q_{305} , 2SK19GR, generates a signal between 133.3 MHz and 137.3 MHz which is determined by L_{301} , TC_{301} , C_{324} , D_{305} and D_{306} . The varactor diode, D_{305} , changes the frequency by the DC voltage which is delivered from the phase detector amplifier Q_{301} , 2SK19GR. The varactor diode, D_{306} , is used to shift the oscillating frequency in accordance with the band switch setting for a stable lock of the VCO. The output from the VCO, Q_{305} , is fed through a two stage buffer amplifier Q_{306} , 2SK19GR, Q_{307} , 2SC784R, to the mixers, Q_{405} in receive, Q_{501} and Q_{502} in transmit.

A portion of the output from Q_{306} is amplified through the buffer amplifier Q_{304} , 2SC372Y, and is fed to the mixer Q_{303} , 2SC372Y, where the signal from local oscillator unit is converted into a 8,000 to 8,500 kHz comparison signal.

This comparison signal is amplified by the amplifier Q_{302} , $\mu A703HC$ and fed to the phase detector circuit consisting of diodes, D_{303} and D_{304} , 1S-1007.

The phase detector compares the phase of the comparison signal with that of the reference signal which is fed through pin 17 from the FIX unit (VFO or FIX crystal signal), and any phase difference is converted into an error correcting voltage. This error voltage is amplified by Q_{301} , **2SK19GR**, and fed to the varactor diode D_{305} , **1SV50**, which changes the output signal phase to track the input.

The programmable unijunction transistor D_{301} , N13T1, generates a sawtooth wave when the VCO is unlocked. The sawtooth wave is used to lock the VCO. A portion of it is fed to the inverter Q_{308} , and rectified by Q_{310} 1S1555.

The rectified voltage causes Q_{309} , 2SC372Y, to conduct and its emitter voltage is used to conduct Q_{607} in the AF unit thus shorting the audio input to quiet the receiver when the PLL is unlocked.

In transmit, this voltage controls Q_{507} in the EXCITER unit causing Q_{506} cut off to disable the exciter stages. Thus, the transmitter and receiver stop functioning when the VCO is unlocked. With this voltage, a multivibrator Q_{308} , **TP4011AN**, produces a blanking pulse which controls the pilot lamp driver Q_{310} , **MPSA13**, causing the pilot lamp to flicker indicating VCO unlock.



Figure 20

MARKER UNIT (PB-1459)



The crystal marker generator Q_{701} , 2SC372Y, generates a 1 MHz signal, and its output is fed through the buffer amplifier Q_{702} , 2SC372Y, to the frequency divider Q_{703} , SN7490N, where the 1 MHz signal generates a 100 kHz marker signal. When the marker switch is ON, the antenna relay is activated to disconnect the antenna.

Potentiometers VR_1 through VR_8 are installed in this board. These potentiometers are set to change the tuning frequency of the VCO and the exciter tuning circuits.

TONE BURST UNIT (PB-1461)

The tone burst signal is automatically transmitted in the following manner. When the PTT switch of the microphone is pressed momentarily before a normal transmission, the rapid voltage change in the PTT circuit causes a pulse to be fed to the tone burst control circuit consisting of Q_{1001} , Q_{1002} , Q_{1003} , **TP4011AN**, and Q_{1004} , **TP4049AN**, thus activating the tone burst oscillator Q_{1003} , **TP4011AN**.

Normal push-to-talk operation does not produce a pulse to activate the tone burst oscillator.

The tone frequency may be adjusted to any frequency between 1000 to 2000 Hz with VR_{1002} and the tone burst duration may be adjusted with VR_{1001} . The tone signal output level may be adjusted with VR_{1003} . The output from the tone burst oscillator is fed through the buffer Q_{1006} , **2SK19GR**, to pin 29 in the MIC AMP unit.



Figure 22 TONE BURST UNIT PB-1461

POWER SUPPLY & REGULATOR UNIT (PB-1469)

The power supply has been designed to operate from 100/110/117/200/220 or 234 volts AC 50/60 Hz, or 12 volts DC, negative ground. Inserting the appropriate power plug into the rear panel receptacle makes the necessary connections to operate the supply in either mode, AC or DC.

For AC operation, the DC voltage is supplied from the bridge connected rectifier unit D_{150} , M4B-5, which is connected to a 20 volt, 3.5 amps secondary winding of the power transformer. The DC voltage is regulated at 13.5 volts by the voltage regulator circuit consisting of Q_{1501} , 2SD313D, and Q_1 , 2SD114.

Since such circuits as the VFO, local oscillator PLL circuit, require an extremely stabilized voltage, the 13.5 volts DC voltage is further stabilized at 8 volts by the voltage regulator Q_{1503} , 2SC735Y, Q_{1504} , 2SD313D, and Q_{1505} , 2SC372Y.

For DC operation, the positive voltage is connected to pin 3 and the negative voltage to pin 4, of the power receptacle, J_1 . To protect the circuits from any reverse connection of the DC voltage, D_1 , DS130YD, conducts heavily in the reverse polarity connection to blow the line fuse in the DC cord. It is placed between pin 3 and ground on J_1 .













BOTTOM VIEW



MAINTENANCE & ALIGNMENT

GENERAL

Your model FT-221R transceiver has been carefully aligned and tested at factory prior to shipment. The reliability of the solid-state devices used in the FT-221R should provide years of trouble free service if the transceiver is not abused and normal, routine maintenance is carried out.

The following precautions should be observed to prevent damage to the transceiver:

- (1) Do not interchange the AC and DC power cords.
- (2) Do not apply any AC voltage other than the voltage determined by the transformer wiring.
- (3) Do not exceed 14 volts DC, at the POWER receptacle, on DC operation. When operating mobile, check the battery voltage under the load (transmitter "keyed" in FM mode) with the engine running fast enough so the ammeter shows a "charge". In addition, do not operate the FT-221R if the supply voltage is below 12 volts DC.
- (4) Avoid direct exposure to sunshine or water.

ROUTINE MAINTENANCE

Routine maintenance should be limited to keeping the transceiver clean, and periodic performance checks of the transmitter RF power output and the receiver sensitivity.

Cleaning:

When the transceiver has been used in dusty or sandy areas, the interior should be periodically cleaned. A vacuum-cleaner, or low pressure air source should be used, while any accumulated dirt may be removed with a soft brush. Check that the interior is thoroughly dry before replacing the case and/or operating the equipment. Wipe the exterior with a damp cloth whenever required.

PERFORMANCE CHECKS

Make all performance checks at 13.5 volts DC (under load) or AC with the appropriate voltage as determined by the transformer wiring.

Check the transmitter output as follows:

- (a) Connect a suitable 50 ohm dummy load/RF wattmeter to the ANT receptacle.
- (b) Set the MODE switch to FM and key the transmitter while observing the power output. The power should be approximately 10 watts, and the S-meter should read between 6 and 8.
- (c) Set the MODE switch to SSB and key the transmitter. Speak normally into the microphone. The output meter should show 3 to 5 watts mean value.

Check the receiver sensitivity as follows:

- (a) Connect an AC VTVM to the SP receptacle, set the MODE switch to FM and set the SQUELCH control fully counter-clockwise.
- (b) Connect the RF output of a precision, VHF signal generator to the ANT receptacle and with no signal input note the VTVM reading. Adjust the VOLUME control and VTVM range, as required, to obtain an approximate full scale reading. (DO NOT change the VOLUME control setting after this adjustment is made.)
- (c) Set the signal generator to the receiving frequency of the transceiver and adjust the output amplitude of the signal generator until the VTVM reads 1/10th (20 dB decrease) of the reading in step (b). The signal generator output voltage at this point is the 20 dB quieting sensitivity, and should be approximately 0.3μ V.
- (d) Set the MODE switch to SSB position and connect the AC VTVM to the speaker output. Apply an unmodulated, 0.5μ V signal, from the standard signal generator and tune the transceiver for a maximum VTVM reading.
- (e) Set the RF GAIN control to the fully clockwise position and adjust the AF GAIN control for a 450 mV VTVM reading.
- (f) Reduce the signal generator output and read the VTVM reading. The VTVM reading should be less than 45 mV for a 10 dB S/N ratio.

If the above performance checks indicate a need for realignment it is recommended that the transceiver be returned to the dealer for alignment. The alignment procedures require special test equipment and techniques not normally available to the average owner. Attempts to realign the tuned circuits without proper test equipment will result in degraded performance of the transceiver.

ALIGNMENT

SOME OF THE FOLLOWING ALIGNMENT PROCEDURES REQUIRE SPECIAL TEST EQUIPMENT AND TECHNIQUES AND SHOULD ONLY BE DONE BY AN EXPERT TECHNICIAN.

AF AMP UNIT



Figure 26

(1) CW Break-In

Adjust VR_{601} , DELAY control, for a suitable release time.

(2) CW Sidetone Level

Adjust VR_{604} for a suitable side tone level.

(3) Relay Sensitivity & Antitrip

Set the controls as follows:

1	/R ₆₀₂	REL	A	Y			•	•	e,	· Fully CCW
N	AIC G.	AIN ·	3	•	٠	•	•	•		· Fully CCW
Ĭ	/OX G	AIN	ì		•			÷	•	$\cdot PTT$
N	AODE									· LSB or USB

Slowly rotate the RELAY control, VR_{602} , until the relay activates, then return the control carefully counter clockwise until the relay releases. This release point is the proper setting for the RELAY sensitivity control. Set the MIC GAIN control to the 2 o'clock position and the VOX control on the front panel to the 12 o'clock position. Speaking normally into the microphone, make sure that your voice activates the relay. Tune in a signal and adjust the AF GAIN on the front panel to a comfortable listening level. Set the ANTITRIP control, VR_{603} , to the minimum point that will prevent the speaker output from tripping the VOX. Adjust the DELAY control, VR_{601} , for a suitable relay release time.

(4) Discriminator Meter Center

Set the controls as follows:

CHANNEL···VFO MODE ·····FM DISC ·····OFF (down position) RF GAIN ····Fully CW MARKER····ON (up position)

Tune the transceiver for maximum S-meter reading at a marker signal. This maximum reading has a 3 kHz width and the VFO should be set to the center of the signal. Turn the DISC switch on and adjust the center potentiometer, VR_{605} , until the meter indicates mid point on the scale. Check that the meter moves equally toward both ends when the VFO frequency is shifted equally up or down. Shift the VFO frequency 10 kHz lower than the zero center meter indication, and adjust the DISC potentiometer, VR_{606} , until the meter indicates 2.

MARKER UNIT



(1) Frequency Adjustment

Connect a frequency counter, through a 100 PF capacitor, to the collector of Q_{702} , 2SC372Y. Adjust TC₇₀₁ to set the crystal frequency to 1 MHz.

When the counter is not available, use another H.F. receiver and calibrate the 1 MHz signal against WWV or JJY.

(2) Voltage Adjustment for the Varicap Tuning Circuit

Measure the voltage at pins 3, 4, 5, 6, 7, 8, 9 and 10 with a VTVM connected between the pins and ground.

Adjust the appropriate potentiometer, VR_{701} to VR_{708} , for following pin voltages:

Pin No.	3	4	5	6	7	8	9	10
Adjust. VR No.	701	702	703	704	705	706	707	708
Volt. DC. V.	2.0	2.5	3.0	3.5	4.0	4.5	5.0	5.5

Table 3

SSB IF UNIT



(1) S Meter Setting

Disconnect the antenna from the coax receptacle. Set the MODE switch to the AM mode. Set the RF GAIN control on the front panel to the fully clockwise position. Adjust VR_{913} (ZERO) until the meter indicates zero. Then set the RF GAIN control to the fully counter clockwise position. Adjust VR_{902} (FULL SCALE) until the meter indicates full scale. Repeat above procedures until the meter indicates zero and full scale with above mentioned RF GAIN settings. (2) Carrier Balance (SSB Receive)

Disconnect the antenna.

Set the MODE switch to either the LSB or USB modes, and the RF GAIN control fully counter clockwise. Adjust VR_{901} and TC_{901} (CARRIER BALANCE) alternately until the S-meter indicates full scale. Change the MODE switch to CW position and check if the S-meter indicates exactly full scale.

MIC AMP UNIT



(1) SSB Carrier Frequency

Connect a dummy load, such as the YAESU YP-150, to the antenna receptacle and the output of an audio oscillator to the microphone input. Set the MODE switch to an SSB mode. Apply 1 kHz audio signal to the microphone input and adjust the MIC GAIN control or the output level from the audio oscillator for 10 watts RF output on the dummy load. Change the audio frequency to 350 Hz, and adjust TC_{1102} for LSB and TC_{1103} for USB to obtain 2.5 watts output. Check if the power output decreases to 2.5 watts when the audio frequency is moved to approximately 2600 Hz.

(2) AM and CW Carrier Frequency

Tune the transceiver in the USB mode and monitor the transmitted USB signal for the most natural voice quality while using another receiver. Change the mode of the transceiver to AM (with the monitor receiver in the USB mode), and adjust TC_{1104} for a zero beat against a carrier signal.

(3) Carrier Balance (SSB Transmit)

Connect a dummy load to the antenna receptacle and the RF probe of a VTVM to the inner conductor of coax cable at the antenna receptacle. Set the MODE switch to the LSB mode. Set the MIC GAIN control to the fully CCW position. Set the VOX switch to MOX position. Adjust VR_{1102} and TC_{1101} (CARRIER BALANCE) alternately to minimize the VTVM reading.

Repeat this procedure until a minimum reading is obtained equally for both side bands.

(4) CW Carrier Level

Set the CW level control, VR_{1105} , to the point where the output power starts to saturate.

FIX UNIT



The crystal frequency may be precisely adjusted with TC_{101} to TC_{111} for on-frequency crystal controlled operation.

LOCAL UNIT

Set the MODE switch to USB, the BAND switch to 144.0, the CHANNEL switch to VFO, the MARK switch to OFF and the RPT switch to the OFF position. Connect a frequency counter to TP_{201} and adjust the oscillator frequency to 41.7666 MHz with TC_{201} . Set the MARK switch to the ON position and zero beat against the marker signal at 144.0 MHz on the VFO tuning dial. Set the BAND switch to 144.5 MHz and adjust TC_{202} to zero beat, then adjust TC_{203} for 145.0 MHz, TC_{204} for 145.5 MHz, TC_{205} for 146.0 MHz, TC_{206} for 146.5 MHz, TC_{207} for 147.0 MHz and TC_{208} for 147.5 MHz for a zero beat against the marker signal.

For the U.S. model, set the RPT switch to REV, the AUX/600 kHz switch to 600 kHz and the BAND switch to 146.5. Adjust TC_{210} for zero beat. Change the BAND switch to 147.0 and adjust TC_{211} for zero beat. For the European model, set the BAND switch to 145.0 and adjust TC_{210} for zero beat. During the above repeater frequency adjustment, the VFO dial is set to the zero beat obtained in the preceding adjustment.

For the frequency split other than 600 kHz, the crystal calculated by the formular in page 12 is installed in X_{209} socket for 146.5 MHz band and in X_{212} socket for 147.0 MHz band. Set the AUX/ 600 kHz switch to AUX position.

For the split frequency in 100 kHz order, such as 800, 900 or 1000 kHz, use the internal marker signal to calibrate as described in 600 kHz procedures. Adjust TC_{209} for zero beat on 146.5 MHz band and TC_{212} on 147.0 MHz band.

When the split frequency is not in 100 kHz order, such as 850 kHz or 940 kHz, the internal marker signal can not be used. In such a case, connect a precise frequency counter between TP_{201} and ground and adjust TC_{209} or TC_{212} for exact frequency which is 3rd harmonics of the crystal frequency given from the formular. For example, the counter frequency should be 42.31666 MHz for 850 kHz split on 146.5 MHz band, as the crystal frequency is $(127.8 - 0.85) \div 9 = 14.1055$ MHz.



Figure 31

PLL UNIT





This unit does not require any adjustment unless major components are changed, and, as such, requires precise measuring equipment for alignment. When the PLL circuit is unlocked, the pilot lamps start flikering. Adjust VR_{301} until the circuit locks and the pilot lamps stop flikering. Check that the circuit locks at all segments and entire VFO range.

RX RF UNIT



Figure 33

Set the BAND switch to 144.0, the CHANNEL switch to VFO, the RF GAIN control fully clockwise and the MODE switch to the USB mode. Tune the VFO to a signal (144.20 MHz, 10dB) from a signal generator connected to the antenna receptacle. Peak TC_{401} , TC_{402} , TC_{403} and TC_{404} for a maximum S-meter reading. In areas that use the high side of the band, 146 to 148 MHz, it is recommended to perform above procedures on 146.20 MHz.

EXCITER UNIT/BOOSTER UNIT





 $\mathsf{TC}_{1201} \quad \mathsf{Q}_{1201} \quad \mathsf{TC}_{1202} \quad \mathsf{CC}_{1203} \quad \mathsf{TC}_{1204} \quad \mathsf{VR}_{1202} \quad \mathsf{VR}_{1201}$



Figure 35

(1) Power Output

It is recommended that an insulated wand be used for the alignment of the booster unit. Connect a dummy load to the antenna receptacle. Set the BAND switch to 145.0, the CHANNEL switch to VFO and the MODE switch to FM. Set the VFO to 145.0 MHz. Set the VOX control to the MOX position. Peak TC_{501} through TC_{508} and TC_{1201} through TC_{1204} for maximum power output.

Change the frequency to 144.1 MHz and repeat above procedures for maximum power output. Change the frequency to 147.9 MHz and repeat above procedures for maximum power output.

Repeat the procedures alternately on 144.1 MHz, 145.0 MHz and 147.9 MHz until unity power output is obtained over 144 to 148 MHz.

(2) PO Meter Set

The PO (Power Output) meter indicates relative power output. After the completion of the above power output alignment, set the meter control, VR_{1202} , to the point where the meter indicates 80% of full scale.

(3) AM Carrier Level

Set the MODE switch to the AM position. Adjust VR_{502} , in the EXCITER UNIT, for 2.5 watts unmodulated carrier output on the dummy load.

(4) ALC Threshold

Connect the output from a two-tone signal generator to the microphone input and dummy load to the antenna receptacle. Set the BAND switch to 145.0, the CHANNEL switch to VFO, the MODE to USB and the MIC GAIN to the 12 o'clock position. Set the VOX GAIN control to the MOX positoin. Apply a 1 kHz single tone signal at first and adjust the signal generator output until the power meter shows 2.5 watts. Then apply a 1.5 kHz single tone signal and adjust its output for 2.5 watts output. Then leave the output levels of both tones at the set level and apply a 1 kHz/ 1500 kHz, two tone signal, of the above set level. Adjust VR₁₂₀₁ until the power meter indicates 3 watts.

SQUELCH THRESHOLD

Disconnect the antenna. Set the BAND switch to 144.0, the CHANNEL switch to VFO, the RF GAIN to the fully CW position, the MODE switch to FM and SQUELCH control to the 9 o'clock position. Adjust VR_{1401} to the point where the receiver is just silenced. Do not go beyond this threshold point or the SQUELCH control on the front panel will not function properly.

FM DEVIATION ADJUSTMENT

Connect a dummy load and FM deviation meter to the antenna receptacle. Set the MODE switch to FM and the MIC GAIN control to the 2 o'clock position. Apply a 20 mV, 1 kHz audio signal to the microphone input, and set the VOX control to the MOX position. Adjust VR_{1101} in the MIC AMP UNIT for a deviation of ±5 kHz.



Figure 36



Figure 37

The adjustment of this unit should be done after the above FM deviation alignment has been completed. Set the controls, switches and the deviation meter as described in the deviation adjustment. Remove the tone burst unit from the chassis and disconnect the connection of the two test points as illustrated in order to obtain a continuous tone signal during the alignment. Insert the unit into its socket.

Set the MIC GAIN control to the 2 o'clock position and the VOX GAIN control to the MOX position. Measure the burst tone signal frequency at the deviation meter output. Adjust VR_{1002} to the desired frequency. Adjust VR_{1003} for ±3.5 kHz deviation. Set the VOX GAIN control to the PTT position and remove the unit from its socket. Reconnect the disconnected test points and reinstall it into its socket.

The burst signal is automatically transmitted when the PTT switch on the microphone is keyed twice as, i.e., key 0.5 second, receive 0.5 second and then transmit. The deviation of the burst signal is preset at the factory to approximately 0.5 second. It may be adjusted with VR_{1001} . A clockwise rotation produces a longer deviation.

REGULATOR UNIT

Use an AC supply for this alignment. Connect a VTVM DC probe to the 13.5 volt line of the power supply unit. Adjust VR_{150} for a 13.5 volt VTVM reading. Connect the VTVM to the 8 volt line and adjust VR_{1502} for a 8 volt VTVM reading.





Figure 39



CONNECTOR RESISTANCE CHART

UNIT	FIX	LOCAL	PLL	RX RF	EXCITER	AF AMP	MARKER	FMIF	SSB IF	TONE BURST	MIC AMP
PIN	J_{12}	J ₁₃	J_{14}	J ₁₅	J ₁₆	J 17	J_{18}	J 19	J ₂₀	J ₂₁	J_{22}
1	Е	E^{i}	E	Е	Е	Е	E	E	E	Е	Е
2	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	E	0	2.6 K	250	0	53 💥	5.5K	E	1.7 K	Е
3	~	0	2.3 K	_	250	53 ※	2.4 K	Е	3.5 K	-	6K
4	00	- ,	53 💥	Е	0	74 ※	2.5 K	500	-	450	3.2K
5	00	Е	Е	0	6K	_	2.5 K	10	700	53	300
6	00	Е	45 ※	~	E	00	3 K	1 K	-	53	Е
7	00	53	160 ※	0	E	0	3 K	300	250	~	Е
8	00	-	Е	Е	2.4 K	0	3 K	1.6K	-	2.4 K	0
9	Е	Е	2 K	0	2K	40 💥	2.7 K	Е	53※	2.4 K	12K
10	Е	Е	160 💥	Е	2.6K	Е	2.3 K	2.5K	-	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	700
11	00		uli — Tr	53 ※	2.6K		E	Е	E	350	Е
12	53 💥		53 ※	Е	100K	1.6K	∞	-	_	_	Е.
13	00	-	Е	2.4 K	1.1 K	850	E	53*	700K	-	Е
14	00		Е	3.5 K	E	1 K	-	3.3K	-	850	700K
15	00		0	3.3 K	E	2.1 K		100 K	250	-	250
16	00	-	-	Е	E	1.5 K	2.4 K	Е	500	-	250
17	00	-	00	0	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	5.5K	E	0	2.6 K	-	Е
18	Е		Е	£	E	Е	Е	Е	46 ※	Е	E
19		-							-		Е
20		-							-		650
21		~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~							300		53 💥
22		54 💥							—		500
23		-							400		Е
24		-							400		Е
25		-							~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~		9K
26		-							-		0
27		-							53*		9 K
28		-							500		×.
29		-				The second			4.5 K		850
30					1.	1 in	above		Е		2.2K
31		_				1		hien	Е		~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~
32		_				in the	01.16	6-010	500		5K
33		17K							1.9K		00
34									E		1K
35		E							E		Е
36		E							E		Е

Switch, Knob Position POWER...OFF MODE...FM BAND...144.0 CHANNEL...VFO RF GAIN...MAX VOX GAIN...PTT AF GAIN MIC GAIN... SQUELCH FUNCTION SW...OFF Measured with 20K Q/V Values are in OHMS

						-				-																													
		FM	L	E	ы	0	0	8 0	. F	। मि		7.2	1.6	E	ы	E	0	0	8.0	뇌	E	ম	0	8.0	0	ਸ਼	ы	0	0	0.9	0	0	0	0	0	0	0	E	[L]
		ц	R	E	E	0	0	C) II	E		0	1.8	E	E	E	0	0	0	ы	되	Э	0	8.0	0	Э	되	0	0	0.9	0	0	0	0	0	0	0	E	뇌
		M	F	ਸ਼	ы	0	7.3	8	E	(H)	C	0	1.6	E	ы	ы	0	0	8.0	Ľ	E	Ĺ	0	0	0	E	ы	0	0	0.9	0	0	0	0	0	0	7.3	E	ы
		AM	Я	斑	ы	0	0	0) (F	[I]	0	0	1.8	Э	٤	E	0	0	0	[±]	되	E	0	8.0	0	ĿЛ	띠	0	0	0.9	0	0	0	0	0	0	0	E	ы
	AMP	M	L	E	ы	0	7.3	8.0	- E	٤Ì	C	0	1.6	E	뇌	뇌	0	0	8.0	[7]	되	뇌	0	8.0	0	되	ы	0	0	0.9	0	0	0	0	0	0	7.3	ы	뙤
J22	MIC	CW	R	E	되	0	0	0) [I]	띠	0	0	1.8	되	뇌	٤	0	0	0	E	E	되	0	8.0	0	ы	뇌	0	0	0.9	0	0	7.3	0	0	0	0		ഥ
	M	В	L	E	E	0	0	0) [H]	머	0	0	2.2	띠	E	E	0	8.0	8.0	ы	E	ഥ	0	8.0	0	ы	ы	0	0	0.9	0	0.1	7.3	0	0	0	0	[L]	되
		US	R	ы	ы	0	0	0	1	E	0	0	1.8	E	E	ы	0	0	0	ы	띠	ы	0	8.0	0	ы	ы	0	0	0.9	0	0.1	7.3	0	0	0	0	E	되
		SB	F	ы	ы	0	0	0	E	E	0	0	2.2	ы	ы	ы	0	8.0	8.0	ы	[L]	ĿЛ	0	8.0	0	ы	ਸ਼	0	0	0.9	0	7.3	0.1	0	0	0	0	ഥ	ы
		LS	R	E	ы	0	0	0	E	ы	0	0	1.8	뇌	ы	띠	0	0	0	뇌	[X]	되	0	8.0	0	되	되	0	0	0.9	0	7.3	0.1	0	0	0	0	ы	ы
-	ERST		F	দ্য	E	0	0	8.0	8.0	0	2.0	2.0	0	0	0	0	0	0	0	0	E																		
J_{21}	TONE BURST		R	ы	뇌	0	0	8.0	8.0	0	2.0	2.0	0	0	0	0	0	0	0	0	E																		
0	IF		H	뙤	뇌	2.8	0	2.2	0	8.0	0	0	0	E	0	0	0	8.0	0	0	0	0	0	0	0	0	0	0	0	8.0	0	0	되	되	0	0	ы	ਸ਼	되
J_{20}	SSB		R	ы	뇌	0	0	1.8	0	0	0	8.0	0	ы	0	0	0	0	1.6	7.0	13.5	0	0	0	0	0.85	0.85	0	0	8.0.8	0	0	되	되	0	0	ы	٤	되
		M	L	ы	0	뇌	0	0	0	8.0	0.59	[1]	0	0	0	8.0	4.2	0	E	0	E					0	0												
6	IF	FM	Я	ഥ	0	ы	0.05	0	7.2	0	0.65	E	0	0	7.3	8.0	5.2	0	E	0	ы																		
J_{19}	FM	ILSB	F	म	0	ы	0	0	0	8.0	0.65 (ы	0	0	0	8.0	4.2	4.7	ы	0	ы																		
		USB.LSB CW.AM	R	ы	0	ы	0	0	0	0	0	ы	0	0	0	8.0	5.2	5.00	띠	0	되																		
	ER		н	ы	8.0	2.0	2.5	3.0	3.5	4.0	4.5	5.0	5.5	ы	0	(۲)	0	0	0	দ্র	E																		
J_{18}	MARKER		R	ы	8.0		2.5		3.5	4.0	4.5	5.0	5.5	(II)	0	뇌	0	0	0	ы	E																		
		>	T	ы	0	8.0	0.5	0	0	0	0	3.5	0	1	0.55	0	0	0	0	0	ы																		
	AMP	CW	R	ы	0	8.0	13.5	0	0.6	0	0	13.5 1	- 0		0	0	0	0	0	0	ы																		
J_{17}	AF A	MM	T	ы	0	8.0	0	0	0.6	0	0	13.5]	0	1	0.65	0	0	0	0	0	ы															_			
	1	USB.LSB CW.FM	R	ы	0		13.5	0	0.6	0	0	13.5]	0	1	0	0	0	0	0	0	ы																		-
			L	ш	0		0	0	E	E	2.0		12.4	12.6	0.9	13.5	۲. ۲	ы	뇌	0	ы										-					_			-
		FM	Я	ы	0	0	0	0	ы	E	2.0		0		6.0		ы	ы	되	0	되							+										-	-
		Ν	F	ы	0	0	0	0	ы	ы	2.0	0	4.3	3	0.9 (13.5	ы	ы	ы	0	Ш																	+	
9	TER	AM	Ж	ш	0	0	0	0	ы	ы	2.0	0	0		0.9 (되	ы	ы	0	म															_		-	-
J_{16}	EXCITER	~	H	ы	0	0	0	0	ш	ы	2.0	0	12.4			13.5	되	되	ы	0	되												+			-			-
	Щ	CW	щ	ш	0	0	0	0	ы	ы	2.0	- 1	- 1		-		되	되	ы	0	ы																		
	~	LSB	F	ш	8.0	8.0	0	0	E	ы	2.0	0	13.0			13.5	ы	ы	ы	0	ы		-						+									-	
8		USB.	R				0	0	E	ы	2.0		1.1		CD I		ы.	<u>ل</u> ي	ы	0	ы			1	+			-	-	+		+	+				-	_	
	RF		H	ы.	0	0	ы	0	0	0	ы	0	E			2.0	2.8	4.2	ы	0	ы								1		1	-	-	-				-	
J 15	RX		Ж	EI (7.2	0	E	0	0	0	ы	0	E	8.0				N	ы	0	Ē					+			+		+				-			-	-
	Ц		F		-	-	_	ы	0	0.7	ы				_				-	0	ш	+	+	+				+		-			-		+			+	-
J_{14}	PLL	ŀ	Ж	ы ы			0	ы	0	N	ഥ						-				ы		-			-				+					+			-	
	AL		F	ы ы				-	ਸ਼	8.0 0	0	ы	-			-		-		-	-	0	0	0	8.0	0 0	0 0	0 0	0 0	0 0	0	0	0	0	0	0	0	3.8	뇌
J_{13}	LOCAL		Я	ы r	괴	0	-	-	ਸ਼	8.08	-	ы	-		-	-		-	-		+		-		0	-	-	-	+		-	-	-	-	-	-		~	<u>н</u>
			H	<u>ы</u> (0	0	+		_		-	-	-	-	0		-	-	-	-	E	+	-		00			-	+	+	-	-			-	-		m	-
J_{12}	FIX		+		-	-		0		-	-	-	+		0	-	-			-	뇌	+	+	-		+	+	-	+		-		+			-		+	년 년 년
[TINU		+	+	+	-	-	+	-	-	-	-	-			-	-	-	+	-		5	,		2 0	2	4 L	0 0	0 1	- 0	0 0	5 0			2		4	5	
_	Б				-		4.			-	~							1	-	17	18	19	20	17	22	N C	247	07	07	17	07	67	30	31	32	33	34	35	36

CONNECTOR VOLTAGE CHART

Measured with VTVM. Values are in VOLTS DC.

VOLTAGE CHART

FIX Unit

	E	В	С		Е	В	С
Q 101	0.9	1.4	7.7	Q 102	2.2	2.9	5.8

LOCAL Unit

	Е	В	С		Е	В	С		Е	В	С
Q 201	2.4	2.5	7.6	Q 202	1.1	1.3	7.9	Q 203	0.9	1.4	7.6

PLL Unit

	E(S)	B(G)	C(D)		E(S)	B(G)	C(D)		E(S)	B(G)	C(D)
Q 301	1.6	0	4.5	Q 305	0.9	0	5.4	Q 309	0	0	8.0
Q 303	0.9	1.4	8.0	Q 306	1.0	0	5.9	Q 310	0	0.7	1.3
Q 304	0.5	1.1	7.5	Q 307	0.5	0.8	7.2				

	1	2	3	4	5	6	7	8	.9	10	11	12	13	14
Q 302	7.2	-	1.5	Е	1.5		7.2	7.5						
Q 308	4.9	4.9	0.2	8.0	0	1.9	Е	8.0	8.0	0	8.0	0	0	8.0

RX RF Unit

	E (S)		B (G)		C (D)		G2			E (S)		B (G)		C (D)	
	R	Т	R	Т	R	Т	R	Т		R	Т	R	Т	R	Т
Q 401	1.5	0	1.6	0	8.0	0.1	3.9	0	Q 404	0.7	0	1.4	0	7.9	0.1
Q 402	1.6	1.1	0	0	• 7.9	0.1			Q 405	1.0	0	0	0	7.7	0
Q 403	1.2	0	1.8	0	7.8	0.1									

EXCITER Unit (on Transmit)

	LSB	USB	.CW	1	AM.FM	vi -		LSB.USB.CW			AM.FM				LSB.USB.CW			AM.FM		
	E (S)	$B\left(G ight)$	$C\left(D\right)$	$E\left(S ight)$	B (G)	$C\left(D\right)$		E(S)	B (G)	C (D)	$E\left(s ight)$	B (G)	C (D)		$E\left(S ight)$	B (G)	C (D)	E (S)	$B\left< G \right>$	C (D)
Q 501	1.3	0	12.1	1.4	0	11.8	Q 504	0.4	1.2	10.1	0.4	1.2	10.0	Q 507	0	0	13.3	0	0	13.3
Q 502	1.3	0	12.1	1.4	0	11.7	Q 505	0	0.7	13.4	0	0.7	13.4	Q 508	1.1	1.8	5.4	1.1	1.8	5.4
Q 503	1.2	1.9	12.0	1.2	1.9	11.9	Q 506	12.5	13.3	13.5	12.5	13.3	13.5	Q 509	4.9	5.5	13.5	4.9	5.5	13.5

Receive 0 V
AF AMP Unit

	LSE AM	USB.	.CW		FΜ			LSE AM	B.USB	.CW		FΜ			LSE AM	B.USB	.CW		FΜ	
	E(S)	$B\left(G\right)$	$C\left(D\right)$	E(S)	$B\left(G\right)$	$C\left(D\right)$		E(S)	B (G)	C(D)	$E\left(s\right)$	$B\left(G\right)$	$C\left< D \right>$		$E\left(\mathrm{S} ight)$	B (G)	C(D)	$E\left(S\right)$	B (G)	C (D)
Q 601	0.4	1.0	7.0	0.4	1.0	7.0	Q 607	0	0	0.6	0	0	0.6	Q 612	13.5	12.9	7.5	13.5	12.9	7.5
Q 603	0.4	0	0.6	0.4	0	0.6	Q 608	0	0	0	1.9	0	* 5.7	Q 613	6.8	7.4	13.5	6.8	7.4	13.5
Q 604	0	0.6	12.9	0	0.6	12.9	Q 609	0	0	0	2.6	0	6.3	Q 614	6.8	6.2	0	6.8	6.2	0
Q 605	0.4	1.0	5.8	0.4	1.0	5.8	Q 610	0	0.6	3.8	0	0.6	3.8							
Q 606	2.9	1.0	8.0	2.9	1.0	8.0	Q 611	8.5	9.1	12.9	8.5	9.1	12.9							

★FM Transmit……0V

	1	2	3	4	5	6	7	8	9
Q 602	4.7	2.8	2.2	2.1	0	0.5	0.7	1.1	8.0

MARKER Unit (Marker Switch ON)

	Е	В	С		Е	В	С
Q 701	1.9	2.4	8.0	Q 702	0	0.3	1.6

	1	2	3	4	5	6	7	8	9	10	11	12	13	14
Q 703	1.6	0	0	0	5.1	0	0	1.4	1.4	0	0.7	1.7	0	0.7

FM Unit

	LSE	USB	CW		FΜ			LSE AM	B.USB	.CW		FΜ		\backslash	LSE AM	B.USB	CW		FΜ	
	E(S)	B (G)	C (D)	E(S)	B (G)	C (D)		E(S)	B (G)	C (D)	$E\left(s\right)$	B(G)	$C\left(\mathrm{D}\right)$		$E\left(s ight)$	B (G)	C(D)	$E\left(s\right)$	$B\left(G\right)$	C(D)
Q 801	1.8	2.5	7.7	1.8	2.5	7.7	Q 805	0	0	0	* 1.3	* 0.7	* 7.2	Q 809	0	0	0	0.6	1.3	7.0
Q 803	0	1.9	5.1	0	1.9	5.1	Q 806	0	0	0	* 1.4	* 2.1	2 .5							
Q 804	5.8	5.8	5.3	5.8	5.8	5.3	Q 807	0	0	0	0.7	* 1.4	7 .0							

★FM Transmit……0V

		1	2	3	4	5	6	7	8
Q 802	Τ·R	7.0	_	1.5	0	1.5	—	7.0	7.5
0.000	$FM \cdot R$	1.8	1.8	6.8	0	5.5	1.8	1.8	
Q 808	Τ·R	0	0	0	0	0	0	0	

SSB IF Unit

\square	E	(S)	В	(G)	C	(D)		E	(S)	В	(G)	С	(D)		E	(S)	В	(G)	С	(D)
	R	Т	R	Т	R	Т		R	Т	R	Т	R	Т		R	Т	R	Т	R	Т
Q 901	0.7	0	0.7	0	7.3	0	Q 905	0	0	0.7	0	7.2	0	Q 908	0.3	0.3	1.0	1.0	5.8	5.8
Q 903	1.1	0	0	0	7.8	0	Q 906	0	0.6	0	0	0	7.0							
Q 904	0.7	0	0.7	0	7.3	0	Q 907	5.3	5.3	5.9	5.9	6.8	6.8		4					

		1	2	3	4	5	6	7	8
0.000	R	0	1.2	0	1.8	5.5	7.6	7.3	0
Q 902	Т	0	0	0	0	0	0	0	0

TONE BURST Unit

		1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
0.1001	R	0	0	8.0	0	8.0	8.0	0	0	0	8.0	0	8.0	7.2	8.0		
Q 1001	Т	8.0	8.0	0	8.0	0	0	0	0	0	8.0	0	8.0	7.2	8.0		
Q 1002	R · T	7.2	8.0	0	8.0	0	0	0	0	8.0	8.0	8.0	0	0	8.0		
Q 1003	R·Т	0	0	8.0	0	8.0	7.3	0	8.0	8.0	0	8.0	7.2	0	8.0		
0.100.1	R	8.0	0	7.2	0	7.3	0	8.0	0	0	8.0	8.0	0	0	7.2	0	8.0
Q 1004	Т	8.0	0	7.2	0	7.3	0	8.0	0	8.0	0	8.0	0	0	7.3	0	8.0
Q 1005	R · T	0	8.0	0	0	8.0	8.0	0	0	0	0	0	0	0	8.0	0	8.0

	S	G	D
Q 1006	0.9	0	8.0

BOOSTER Unit (on Transmit)

	LSE	B.USB.	CW		A M			FΜ			LSB	USB	.CW		AM			FΜ	
	$E\left(S ight)$	B(G)	$C\left(D\right)$	$E\left(\mathrm{S}\right)$	B(G)	$C\left(D\right)$	$E\left(s\right)$	$B\left(G\right)$	$C\left(\mathrm{D}\right)$		E(S)	B(G)	C(D)	E(S)	B (G)	C(D)	E(S)	B (G)	C(D)
Q 1201	0	0.7	12.3	0	0.6	3.6	0	0.6	11.7	Q 1202	0	0.7	13.5	0	0.4	13.3	0	0.2	13.1

Receive0V

VFO Unit

	E(S)	B(G)	C(D)		E(S)	B(G)	C(D)		E(S)	B(G)	C(D)
Q 1301	2.1	2.7	4.4	Q1302	1.6	0	7.6	Q 1303	1.6	2.1	6.9

MIC AMP Unit

		L	SB.	US	В				С	W					A	М					F	М		
	Е	(S)	В	(G)	С	(D)	Е	(S)	В	(G)	C	(D)	E	(S)	В	(G)	С	(D)	E	(S)	В	(G)	С	(D)
	R	Т	R	Т	R	Т	R	Т	R	Т	R	Т	R	Т	R	Т	R	Т	R	Т	R	Т	R	Т
Q 1101	0	0	0	0	0	0	0	4.9	0	2.6	0	8.0	0	1.9	0	2.6	0	7.8	0	2.2	0	2.6	0	7.8
Q1102	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0 ,	1.6	0	2.2	0	7.2
Q 1103	1.5	1.5	2.1	2.1	3.9	3.9	1.5	1.5	2.1	2.1	3.9	3.9	1.5	1.5	2.1	2.1	3.9	3.9	1.5	1.5	2.1	2.1	3.9	3.9
Q1105	0	2.2	0	0	0	7.8	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Q1106	0	0.7	0	0	0	7.3	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Q 1107	3.0	3.0	3.4	3.4	6.8	6.8	3.0	4.9	3.4	3.4	6.8	8.0	2.7	3.0	3.4	3.4	6.8	6.7	2.7	2.7	3.4	3.4	6.8	6.8
Q 1108	2.5	2.5	1.9	1.9	6.8	6.8	2.5	2.5	2.1	2.3	6.8	6.8	2.3	2.5	1.4	1.8	6.9	6.8	2.3	2.3	1.3	1.4	6.9	6.9

		1	2	3	4	5	6	7	8	9
0.1101	R	4.1	2.4	1.8	1.7	0	0	0	0.7	6.2
Q 1104	Т	4.1	2.4	1.8	1.7	0	0.5	3.3	1.2	6.9

REG Unit

				15				15			
	Е	В	С		Е	В	C		Е	В	С
Q 1501	14.1	14.6	22.6	Q 1503	8.7	9.3	13.5	Q 1505	6.1	6.7	9.3
Q 1502	9.0	9.7	14.6	Q 1504	8.0	13.5	8.7	Q 1	13.5	14.1	22.5

AM Mod(Q7)

	Е			В	С		
	R	Т	R	Т	R	Т	
USB USB CW	0	12.3	0	12.9	0	13.5	
AM	0	3.6	0	4.2	Q	13.4	
FΜ	0	11.7	0	12.3	0	13.2	

PARTS LIST

			PARI		51		
		N CHASSIS		6,7		SLE-12251	
		CIRCUIT BOA		8		SLE-14201 SLE-14301	
	$(A \sim Z)$ $(A \sim Z)$	LED SWITCH	BOARD	J	JACK	SLE 14001	
1002	$(\mathbf{A} - \mathbf{Z})$	SWITCH	DOARD	1	OAOR	QMS-AB4M	
Q	TRANSIS	TOR		2		CS-250	
1			2SD114	3		SG-7615	
7			2SD313D	4		SG-8050	
				5		FM-144J	
D	DIODE			6		XG-8018	
1		Si Bridge	DS-130-YD	$7 \sim 10$)	CN-7017J	
$6\!\sim\!10$		Si	10D-1	11		SO-239	
11		LED	GD-4		4~19, 21	3305-018-011	
12			RD-4	13, 20), 22	1150-036-009	
13			TLR-108	25		CN-1463	
R	RESISTO	P		P	PLUG		
R		ON COMPOSIT	ION	24	1 LOG	SI-8501	
16	Onne	1/4 W	10KΩ				
15		1⁄4 W	100 ΚΩ	F	FUSE		
19		1/2 W	10 Ω	1		2A	
17		$\frac{1}{2}W$	56 Ω	2		1A	
18		$\frac{1}{2}W$	100 Ω				
14,		$\frac{1}{2}$ W	220 Ω	FS	FUSE H	HOLDER	
13, 21		1⁄2 W	470 Ω	1		SN-1001 #2	
11, 12		$\frac{1}{2}W$	33K Ω				
VR		OMETER	F00000/F00000		PILOT		40 4
4			500 ΩB/500 ΩC	1~3		14V	40mA
5		13A-5M3121	5KA 5KA				
8	EVF VM2	H-BOAS-15A53	5KB	and the second second			
7		1A5M	10KA	PB	PRINTE	D CIRCUIT BOARD	
3		I-BOAS-15B54		1453	$(A \sim Z)$	FIX OSC CIRCUIT	
10		I - BOAS - 15B53	5KB			CRYSTAL BOARD	
9		L-SOAA-00B54	50KB		(/		
C	CAPACIT			Q	TRANSI	STOR	
	I.	DIPPED MICA		101, 1	102	2SC372Y	
16, 17,	, 18	50 W V	100PF				
22		50 W V	300PF		DIODE		
		CERAMIC DISC		101~	111	Si 1S1555	
14, 28		50 W V	0.001µF	X	ODVOT		
33,13		50WV	$0.01 \mu F$	X	CRYST	HC-25/U (O	PTION)
$\frac{11 - 1}{24 - 2}$, 23, 27 50WV 500WV	0.047μF 0.01μF	101~	111	HC-23/0 (0	F HON)
$\frac{24 \sim 20}{1, 2}$	0	1.4KV		XS	CRYST	AL SOCKET	
1, 2		1.410	0.0047/21	101~		S2-101P	
PT	POWER "	TRANSFORME	२				
1		52-36		R	RESIST	OR	
						CARBON FILM	n i hwar
СН	CHOKE C				108, 109	1⁄4 W	100 Ω
1		SN-8S	-500	104		1⁄4 W	_ 220 Ω
				101		1/4 W	1.5KΩ
М	METER			102, 1	107	1/4 W	5.6KΩ
1	•	SP-384	J	106		1/4 W	8.2KΩ
60	CDEALE	D		103	a data la data	1/4 W	22 ΚΩ
SP	SPEAKE		T	С	CAPACI	TOR	
1		SA-701	1	U	CAPACI	DIPPED MICA	
RL	RELAY			130		50WV	15PF
1		AE-317	'1	131		50WV	20PF
-				117~	127	50 W V	30PF
RLS	RELAY S	SOCKET		129		50 W V	100PF
1		AE-386	50	128, 1	132	50 W V	200PF
						CERAMIC DISC	
S	SWITCH			101 ~	116	50 W V	0.01µF
1		ESR-E	22CR15D				
2			48R15A	TC		ER CAPACITOR	
3			85R15A	101~	-111	ECV-1ZW 20×40	20PF
4		SP-202					
5		SLE-1	2301	L	INDUCTO	R	

101~111	EL0610-102K	1mH			PLL UNIT		
112	EL0610-251K FL-3H 1R2M	250µH 1.2µH	PB	PRINTED	PLL CIRC		RD
113	FL-3H IR2M	1.2μΠ	1455	$(\mathbf{A} \cdot \mathbf{Z})$	LL CINC		
			Q	IC FET 8	TRANSI		
LC	CAL UNIT		302		IC		μA703HC
	RCUIT BOARD		308				TP4011AN
1454 $(A \sim Z)$ L	OCAL OSC CIRC	UIT	301		FE		2SK19Y
			305, 3		//		2SK19GR
Q TRANSISTO				04, 309			2SC372Y
201		2SC372Y	307				2SC784R MPSA13
202, 203		2SC784R	310 D	DIODE			MPSAIS
DIODE				DIODE	PUT		N13T1
D DIODE	Si	1S1555	301 309, 3	10	Si		1S1555
201~212 225	~ .	1S188FM	311	10	Ge		1S188FM
226		1SV50	303, 3	04			1S1007
220	Varactor	15 + 50	302		Zener		WZ061
CRYSTAL			305, 3	06	Varact	or	1SV50
201	HC-18/U 13.	92222MHz	307, 3		Varact	tor	1S2209
202	**** ==/ =	97777MHz	R	RESISTO			
203	// 14.	03333MHz		С	ARBON F		
204	// 14.	08888MHz	305			$\frac{1}{4}$ W	22
205		14444MHz	305, 3			$\frac{1}{4}W$	56
206	" 14.	20000MHz	313,33	15,319,320,32			100
207		25555MHz	303			1/4 W	150
208		31111MHz		08, 314, 326,		1/4 W	220
210 (Repeater)		13333MHz)	325			$\frac{1}{4}W$	270
211 (Repeater)		32222 MHz)	307	1.0		$\frac{1}{4}W$	330
US Model		02222MHz)	310, 3			$\frac{1}{4}W$	1K
XS CRYSTAL S				45, 346		$\frac{1}{4}W$	2.2K 4.7K
201	S-14			21, 330		1/4 W	4.7K 10K
			311, 3			$\frac{1}{4}W$ $\frac{1}{4}W$	22K
R RESISTOR	DON DU M		and the second se	18, 322, 331		$\frac{24}{1/4}$ W	47 K
	BON FILM	100 Ω	301	23,324,327,3	-	$\frac{74}{1/4}$ W	100 K
221, 225	1/4 W	220 Ω	309,3	23, 324, 327, 3	,	$\frac{1}{4}$ W	560K
217, 224	14 W 14 W	560 Ω		36, 338, 341,		$\frac{1}{4}$ W	1M:
220	1/4 W	1KΩ	552, 5	CARF	BON COMI		
213, 216 222	1/4 W	2.2KΩ	342	Omm		1/4 W	2.2M
222 201 \sim 212	1/4 W	3.3KΩ	RS	THERM	ISTOR	/4 //	
215, 218	1/4 W	4.7KΩ	301		SDT-	250	
214, 223	1/4 W	10K Ω	VR	POTENT	OMETER		
219	1/4 W	22K Ω	301	KVL-S	SOAA-00E	313	1 K.
C CAPACITOR	20		С	CAPACIT			
	PED MICA				DIPPED N		
242	50 W V	1PF	322, 3	and the second se	50\		5P
239	50WV	5PF	339, 3			NV NV	6P
240, 241	50WV	8PF	318, 3		501		10P
213~224, 236, 238	50 W V	30PF	308, 3			NV NV	20P
237	50WV	39PF	325, 3		501		30P 47P
234	50WV	150PF	323, 3			NV NV	47P 170P
235	50WV	200PF		312, 313		NV NV	200P
	RAMIC DISC	0.01 17	307		ERAMIC		2001
201 - 212, 225 - 230, 201 - 242		$\frac{0.01 \mu \mathrm{F}}{0.047 \mu \mathrm{F}}$	304 2	06,310,311,3			V 0.01µ
231, 243	50WV	0.047μΓ		21,328,329,3		4, 345	. 0.01µ
TC TRIMMER (201~212 E	$CV-1ZW 20 \times 40$	20PF	341			NV	0.01μ
201-212 E	U 12 W 20 40	201.1	343			WV	0.1µ
L INDUCTOR					TANTALU		
203	# 221026	3.2µH	301, 3			WV	0.1µ
203 202, 204, 201	EL0610-220K		, (LECTROL		
	110010 220IX		303, 3			WV	10μ
		1.000	302		16	WV	100 µ
T TRANSFOR	MER	1.888.1	100				
201	R-12 #4797						
201							

TC TRIMMER	CAPACITOR		404, 414, 417	50WV	0.001µF
	ECV-1ZW 10		405~407, 412, 41		0.01µF
302, 303	ECV-1ZW 10		418~420,424,42		
			415,416	50WV	0.047µF
L INDUCTO	R		,	ELECTROLYTIC	
302	FL-3H-3R3N	4 3.3μH	423	16WV	1µF
304, 306	RFC	10µH		ER CAPACITOR	
303, 305	RFC	250µH		ECV-1ZW 10×40	10PF
301	OSC #22101				
002	000 11 22 10				201
T TRANSFO	RMER		L INDUCT	OR	
309	# 221014		401	# 221003	
302, 303	R-12 4102		402	# 221004	
			403	# 221005	
			404	# 221006	
			406	EL0610-220K	22µH
			407	EL0610-251K	250 µH
			405	EL0610-102K	1mF
			T TRANS	FORMER	
			401~404	R-12 4074	
			405	R-12 4102	
128					
				EXCITER UNIT	
	RX RF UNIT		PB PRINTE	D CIRCUIT BOARD	
PB PRINTED	CIRCUIT BOA	RD	1466 $(A \sim Z)$	EXCITER CIRCUIT	
1456 $(A \sim Z)$ R2	X RF CIRCUIT				
			Q FET &	TRANSISTOR	
Q FET & T	RANSISTOR		501, 502	FET 2SI	K19GR
401	FET	3SK51	507, 509	250	C372Y
402,405	"	2SK19GR	508	250	C373
403, 404		2SC372Y	505	250	2730
			506	250	C735Y
D DIODE			504	250	C741
407	G.B	1S1007	503	250	C784R
401~404,408	Varactor	1S2209			1 102 211
			D DIODE		
XF CRYSTAL	- FILTER		505~507	Si 1SI	1555
401	FMT-30		501 - 504, 508	Varactor 1S2	2209
			R RESIST	OR	
				CARBON FILM	
			516	1⁄4 W	10
R RESISTO	R		520, 532	1⁄4 W	56
	ARBON FILM	14945 591	509, 513, 531	1⁄4 W	100
408, 414, 418, 422, 4		100 Ω	512	1/4 W	220
428	1⁄4 W	220 Ω	515	1/4 W	330
417, 421	1/4 W	470 Ω	526	1/4 W	470
413	1/4 W	1KΩ	522	1/4 W	820
409, 426	1/4 W	1.5KΩ	535	1/4 W	1K
423	1/4 W	2.2KΩ	519, 523, 527, 530		2.2K
425	1/4 W	3.9KΩ	514	1/4 W	2.7K
415, 419	1/4 W	4.7KΩ	508, 510	1/4 W	3.3K
416	1/4 W	15KΩ	533	1/4 W	4.7K
405, 420	1/4 W	22KΩ	524	1/4 W	5.6K
403, 404, 406, 407, 4		100KΩ	529	1/4 W	10K
	ON COMPOSIT		511, 528	1/4 W	15K
		1MΩ	525	1/4 W	27KS
401 402 410 411	FOO /4 WV	1 111 52	525	1/4 W	47KS
401, 402, 410, 411, 4	OP			BON COMPOSITION	
			503~507, 536	¹ / ₄ W	1M 9
C CAPACIT			$503 \sim 507, 530$ 534		
C CAPACITO	IPPED MICA	100		1⁄2 W	10 9
C CAPACITO D 422	DIPPED MICA 50WV	1PF	554		
C CAPACITO D 422 401, 402, 408, 409	DIPPED MICA 50WV 50WV	5PF		TIOMETER	
C CAPACITO D 422 401, 402, 408, 409 429	01PPED MICA 50WV 50WV 50WV	5PF 6PF	VR POTEN	TIOMETER	
D 422 401, 402, 408, 409 429 403	IPPED MICA 50WV 50WV 50WV 50WV 50WV	5PF 6PF 30PF	VR POTEN 501	EVL-SOAA-00B13	
C CAPACITO D 422 401, 402, 408, 409 429 403 426	DIPPED MICA 50WV 50WV 50WV 50WV 50WV	5PF 6PF 30PF 47PF	VR POTEN		
C CAPACITO D 422 401, 402, 408, 409 429 403 426 411	DIPPED MICA 50WV 50WV 50WV 50WV 50WV 50WV	5PF 6PF 30PF 47PF 100PF	VR POTEN 501 502	EVL-SOAA-00B13 EVL-SOAA-00B54	
C CAPACITO D 422 401, 402, 408, 409 429 403 426 411 421	DIPPED MICA 50WV 50WV 50WV 50WV 50WV	5PF 6PF 30PF 47PF	VR POTEN 501	EVL-SOAA-00B13 EVL-SOAA-00B54	

511, 512, 514, 519	50 W V	5PF	634,613	1/4 W	47KΩ
507, 508, 516, 523, 537,		10PF	603, 633, 637	1/4 W	100Κ Ω
510, 506, 535	50 W V	20PF	607	1⁄4 W	1 M Ω
528	50 W V	27 PF			
	AMIC DISC			RBON COMPOSITION	0.0340
513 , 534	50 W V	1PF	608,609	1/2 W	3.3MΩ
502, 503		0.001µF	610	½W	5.6MΩ
501, 504, 505, 509, 515		0.01µF	CAE CAE	WIRE WOUND	0.22Ω
517, 518, 520 ~ 522, 52			645, 646	1 W	0.2232
	IYLAR 50WV	0.047µF	RS THERM	AISTOR	
532	CTROLYTIC	$0.047 \mu \Gamma$	601	SDT-250	
525, 527, 529, 531	16WV	10µF	001	551 500	
530	16WV	22µF	VR POTEN	TIOMETER	
533	10111	33µF	605	EVL-SOAA-00B53	5KB
TC TRIMMER C	APACITOR		602,603	EVL-VOAA-00B14	10KB
	$CV-1ZW 10 \times 40$	10PF	604	EVL-SOAA-00B14	10KB
	CV-1ZW 20×51		606	EVL-SOAA-00B54	50KB
	CV-1ZW 20×32	20PF	601	EVL-VOA -00B26	2MB
	A.6.2			-	
L INDUCTOR			C CAPACI		
503	# 221008			DIPPED MICA	
504, 502	# 221009		634, 637	50 W V	200PF
507, 510	# 221018		635	50 W V	280PF
508, 509	# 221017		628	50 W V	330PF
506	# 221036			CERAMIC DISC	
			636	50 W V	$0.047 \mu F$
T TRANSFORM				MYLAR	0 001 5
501	R-12 4073		610, 615	50 W V	0.001µF
502	# 221035		629,630	50 W V	$0.002 \mu F$
			605, 608, 611, 61	19,620 50WV 50WV	0.01µF 0.02µF
AF UN	the second s		616 - 618 614, 631	50 W V	0.02μ F 0.047μ F
	RCUIT BOARD		609	50WV	$0.047 \mu \Gamma$ $0.1 \mu F$
1499 (A \sim Z) AF CI	RCUIT		009	ELECTROLYTIC	0.1/41
	RANSISTOR		601, 612, 623, 62		$1\mu F$
Q IC FET & T 602		3001	621, 622	16WV	4.7µF
			602~604,606,6		10µF
603	FFT 2SK	19Y			
603		(19Y	624	$10 \mathrm{WV}$	
608, 609	" 2SK	K19GR	624 625, 633	10 W V 16 W V	100μF 100μF
608,609 612	" 2SK 2SA	(19GR (695	624 625, 633 627, 632		100µF
608,609 612 614	" 2SK 2SA 2SE	K19GR A695 3529	625, 633	16 W V	100μF 100μF
608, 609 612 614 601, 605, 606, 607, 610	" 2SK 2SA 2SE	(19GR (695) 3529 (372Y)	625, 633 627, 632	16 W V	100μF 100μF
608, 609 612 614 601, 605, 606, 607, 610 611	" 2SK 2SA 2SE 2SC 2SC	(19GR (695) 3529 (372Y)	625, 633 627, 632 M	16 W V 16 W V	100μF 100μF
608, 609 612 614 601, 605, 606, 607, 610 611 604	" 2SK 2SA 2SE 2SC 2SC 2SC	X19GR A695 3529 C372Y C711	625, 633 627, 632 M	16WV 16WV ARKER UNIT	100μF 100μF
608, 609 612 614 601, 605, 606, 607, 610 611	" 2SK 2SA 2SE 2SC 2SC 2SC	X19GR X695 3529 C372Y C711 C735Y	625, 633 627, 632 M PB PRINT	16WV 16WV ARKER UNIT ED CIRCUIT BOARD	100μF 100μF
608, 609 612 614 601, 605, 606, 607, 610 611 604	" 2SK 2SA 2SE 2SC 2SC 2SC	X19GR X695 3529 C372Y C711 C735Y	625, 633 627, 632 M PB PRINT 1459 (A~Z)	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT TRANSISTOR	100μF 100μF 220μF
608, 609 612 614 601, 605, 606, 607, 610 611 604 613	" 2SK 2SA 2SE 2SC 2SC 2SC	X19GR X695 3529 2372 Y 2711 2735 Y 2359	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT FRANSISTOR IC SN7490	100μF 100μF 220μF
608, 609 612 614 601, 605, 606, 607, 610 611 604 613 DIODE	" 2SK 2SA 2SE 2SC 2SC 2SC 2SC 2SC 2SC 2SC	X19GR X695 3529 2372 Y 2711 2735 Y 2359	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT TRANSISTOR	100μF 100μF 220μF
608, 609 612 614 601, 605, 606, 607, 610 611 604 613 DIODE 601~604	" 2SK 2SA 2SE 2SC 2SC 2SC 2SC 2SC 2SC 2SC	C19GR 695 3529 C372 Y C711 C735 Y D359 555	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703 701, 702	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT FRANSISTOR IC SN7490 2SC372	100μF 100μF 220μF
608, 609 612 614 601, 605, 606, 607, 610 611 604 613 D DIODE 601~604 605 R RESISTOR	" 2SK 2SA 2SE 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC	C19GR 695 3529 C372 Y C711 C735 Y D359 555	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703 701, 702 D DIODE	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT TRANSISTOR IC SN7490 2SC372	100μF 100μF 220μF
608, 609 612 614 601, 605, 606, 607, 610 611 604 613 D DIODE 601~604 605 R RESISTOR CAR	" 2SK 2SA 2SE 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC	C19GR 695 3529 C372Y C711 C735Y 0359 555 -5W	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703 701, 702	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT FRANSISTOR IC SN7490 2SC372	100μF 100μF 220μF
608, 609 612 614 601, 605, 606, 607, 610 611 604 613 D DIODE 601~604 605 R RESISTOR CAR 642	" 2SK 2SA 2SE 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC	 C19GR C695 C372 Y C711 C735 Y C359 555 -5 W 10 Ω 	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703 701, 702 D DIODE 701	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT TRANSISTOR IC SN7490 2SC372 Zener WZ050	100μF 100μF 220μF
608, 609 612 614 601, 605, 606, 607, 610 611 604 613 D DIODE 601~604 605 R RESISTOR CAR 642 641	" 2SK 2SA 2SE 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC	C19GR A695 B529 C372 Y C711 C735 Y D359 555 -5 W 10 Ω 22 Ω	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703 701, 702 D DIODE 701 X CRYS	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT TRANSISTOR IC SN7490 2SC372 Zener WZ050 TAL	100μF 100μF 220μF
608, 609 612 614 601, 605, 606, 607, 610 611 604 613 D DIODE 601~604 605 R RESISTOR CAR 642 641 628	" 2SK 2SA 2SE 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC	C19 GR 6695 3529 C372 Y C711 C735 Y D359 555 -5 W 10 Ω 22 Ω 100 Ω	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703 701, 702 D DIODE 701	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT TRANSISTOR IC SN7490 2SC372 Zener WZ050	100μF 100μF 220μF
608, 609 612 614 601, 605, 606, 607, 610 611 604 613 D DIODE 601~604 605 R RESISTOR CAR 642 641 628 647	" 2SK 2SA 2SE 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC	C19 G R 6695 3529 2372 Y C711 C735 Y 0359 555 -5 W 10 Ω 22 Ω 100 Ω 180 Ω	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703 701, 702 D DIODE 701 X CRYS 701	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT TRANSISTOR IC SN7490 2SC372 Zener WZ050 TAL HC-6/U 1MHz	100μF 100μF 220μF
608, 609 612 614 601, 605, 606, 607, 610 611 604 613 D DIODE 601~604 605 R RESISTOR CAR 642 641 628 647 622, 629, 644	" 2SK 2SA 2SE 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC	$\begin{array}{c} (19{\rm GR} \\ 695 \\ 3529 \\ 2372{\rm Y} \\ 2711 \\ 2735{\rm Y} \\ 0359 \\ \hline \\ 555 \\ -5{\rm W} \\ \hline \\ \hline \\ 10{\Omega} \\ 22{\Omega} \\ 100{\Omega} \\ 180{\Omega} \\ 220{\Omega} \\ \end{array}$	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703 701, 702 D DIODE 701 X CRYS	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT TRANSISTOR IC SN7490 2SC372 Zener WZ050 TAL HC-6/U 1MHz	100μF 100μF 220μF
608, 609 612 614 601, 605, 606, 607, 610 611 604 613 D DIODE 601~604 605 R RESISTOR CAR 642 641 628 647 622, 629, 644 626	" 2SK 2SA 2SE 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC	$\begin{array}{c} (19{\rm GR} \\ 695 \\ 3529 \\ 2372{\rm Y} \\ 2711 \\ 2735{\rm Y} \\ 0359 \\ \hline \\ 555 \\ -5{\rm W} \\ \hline \\ \hline \\ 10{\Omega} \\ 22{\Omega} \\ 100{\Omega} \\ 180{\Omega} \\ 220{\Omega} \\ 470{\Omega} \\ \hline \end{array}$	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703 701, 702 D DIODE 701 X CRYS 701 R RESIS	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT TRANSISTOR IC SN7490 2SC372 Zener WZ050 TAL HC-6/U 1MHz TOR CARBON FILM	100μF 100μF 220μF
608, 609 612 614 601, 605, 606, 607, 610 611 604 613 D DIODE 601~604 605 R RESISTOR CAR 642 641 628 647 622, 629, 644 626 611	" 2SK 2SA 2SE 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC	$\begin{array}{c} (19{\rm GR} \\ 695 \\ 3529 \\ 2372{\rm Y} \\ 7711 \\ 7735{\rm Y} \\ 3559 \\ \hline \\ 555 \\ -5{\rm W} \\ \hline \\ 10{\Omega} \\ 22{\Omega} \\ 100{\Omega} \\ 180{\Omega} \\ 220{\Omega} \\ 470{\Omega} \\ 680{\Omega} \\ \hline \end{array}$	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703 701, 702 D DIODE 701 X CRYS 701 R RESIS	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT TRANSISTOR IC SN7490 2SC372 Zener WZ050 TAL HC-6/U 1MHz TOR CARBON FILM ¼W	100μF 100μF 220μF N Y
$\begin{array}{c} 608, 609 \\ 612 \\ 614 \\ 601, 605, 606, 607, 610 \\ 611 \\ 604 \\ 613 \\ \hline \\ \hline \\ \hline \\ 601 \\ \hline \\ 601 \\ \hline \\ 605 \\ \hline \\ $	" 2SK 2SA 2SE 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC	$\begin{array}{c} (19{\rm GR} \\ 695 \\ 3529 \\ 2372{\rm Y} \\ 7711 \\ 7735{\rm Y} \\ 0359 \\ \hline \\ 555 \\ -5{\rm W} \\ \hline \\ 10{\Omega} \\ 22{\Omega} \\ 100{\Omega} \\ 180{\Omega} \\ 220{\Omega} \\ 470{\Omega} \\ 680{\Omega} \\ 1{\rm K}{\Omega} \\ \hline \end{array}$	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703 701, 702 D DIODE 701 X CRYS 701 R RESIS 713 701~708	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT TRANSISTOR IC SN7490 2SC372 Zener WZ050 TAL HC-6/U 1MHz TOR CARBON FILM ½W	100µF 100µF 220µF N Y 685 1005
$\begin{array}{c} 608, 609 \\ 612 \\ 614 \\ 601, 605, 606, 607, 610 \\ 611 \\ 604 \\ 613 \\ \hline \\ \hline \\ \hline \\ 601 \\ \hline \\ 601 \\ \hline \\ 605 \\ \hline \\ $	" 2SK 2SA 2SF 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC	$\begin{array}{c} (19{\rm GR} \\ (695) \\ (3529) \\ (2372{\rm Y} \\ (711) \\ (735{\rm Y} \\ (2359) \\ (2555) \\ (2$	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703 701, 702 D DIODE 701 X CRYS 701 R RESIS 713 701~708 711	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT FRANSISTOR IC SN7490 2SC372 Zener WZ050 TAL HC-6/U 1MHz TOR CARBON FILM ¼W ¼W	100µF 100µF 220µF N N Y 685 1005 1 K 5
608, 609 612 614 601, 605, 606, 607, 610 611 604 613 D DIODE 601~604 605 R RESISTOR CAR 642 641 628 647 622, 629, 644 626 611 601, 616, 638, 639 604, 635, 636 623, 624, 625, 631	" 2SK 2SA 2SE 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC	$\begin{array}{c} (19{\rm GR} \\ (695) \\ (3529) \\ (2372{\rm Y} \\ (711) \\ (735{\rm Y} \\ (2359) \\ (2555) \\ (25$	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703 701, 702 D DIODE 701 X CRYS 701 R RESIS 713 701~708 711 710	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT FRANSISTOR IC SN7490 2SC372 Zener WZ050 TAL HC-6/U 1MHz TOR CARBON FILM ¼W ¼W ¼W ¼W	100µF 100µF 220µF N N Y 685 1005 1K5 10K5
$\begin{array}{c} 608, 609 \\ 612 \\ 614 \\ 601, 605, 606, 607, 610 \\ 611 \\ 604 \\ 613 \\ \hline \\ $	" 2SK 2SA 2SE 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC	$\begin{array}{c} (19{\rm GR} \\ (695) \\ (3529) \\ (2372{\rm Y} \\ (711) \\ (735{\rm Y} \\ (2359) \\ (2555) \\ (2$	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703 701, 702 D DIODE 701 X CRYS 701 R RESIS 701~708 711 710 709	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT FRANSISTOR IC SN7490 2SC372 Zener WZ050 TAL HC-6/U 1MHz TOR CARBON FILM ¼W ¼W ¼W ¼W ¼4 ¼	100µF 100µF 220µF N N Y 685 1005 1K5 10K5 22K5
$\begin{array}{c} 608, 609\\ 612\\ 614\\ 601, 605, 606, 607, 610\\ 611\\ 604\\ 613\\ \hline \\ \hline$	" 2SK 2SA 2SE 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC	$\begin{array}{c} (19{\rm GR} \\ (695) \\ (3529) \\ (2372{\rm Y} \\ (711) \\ (735{\rm Y} \\ (2359) \\ (2555) \\ (2$	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703 701, 702 D DIODE 701 X CRYS 701 R RESIS 713 701~708 711 710	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT FRANSISTOR IC SN7490 2SC372 Zener WZ050 TAL HC-6/U 1MHz TOR CARBON FILM ¼W ¼W ¼W ¼W	100µF 100µF 220µF N N Y 685 1005 1K5 1005 22K5
$\begin{array}{c} 608, 609 \\ 612 \\ 614 \\ 601, 605, 606, 607, 610 \\ 611 \\ 604 \\ 613 \\ \hline \\ $	" 2SK 2SA 2SE 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC	$\begin{array}{c} (19{\rm GR} \\ (695) \\ (3529) \\ (2372{\rm Y} \\ (711) \\ (735{\rm Y} \\ (2359) \\ (2555) \\ (25$	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703 701, 702 D DIODE 701 X CRYS 701 R RESIS 713 701~708 711 710 709 712	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT FRANSISTOR IC SN7490 2SC372 Zener WZ050 TAL HC-6/U 1MHz TOR CARBON FILM ¼W ¼W ¼W ¼4W ¼4W ¼4W	100µF 100µF 220µF N N Y 685 1005 1K5 1005 22K5
$\begin{array}{c} 608, 609 \\ 612 \\ 614 \\ 601, 605, 606, 607, 610 \\ 611 \\ 604 \\ 613 \\ \hline \\ \hline \\ \hline \\ \hline \\ 604 \\ 613 \\ \hline \\ \hline \\ \hline \\ \hline \\ 601 \\ \hline \\ 604 \\ 605 \\ \hline \\ $	" 2SK 2SA 2SE 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC	$\begin{array}{c} (19{\rm GR} \\ (695) \\ (3529) \\ (2372{\rm Y} \\ (711) \\ (735{\rm Y} \\ (255) \\ (555) $	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703 701, 702 D DIODE 701 X CRYS 701 R RESIS 713 701~708 711 710 709 712 VR POTEI	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT FRANSISTOR IC SN7490 2SC372 Zener WZ050 TAL HC-6/U 1MHz TOR CARBON FILM ¼W ¼W ¼W ¼W ¼4 ¼	100µF 100µF 220µF N N Y 685 1005 1K5 1005 1K5 22K5 470K5
$\begin{array}{c} 608, 609\\ 612\\ 614\\ 601, 605, 606, 607, 610\\ 611\\ 604\\ 613\\ \hline \\ \hline$	" 2SK 2SF 2SC 2SC 2SC 24W 24W 24W 24W 24W 24W	$\begin{array}{c} (19{\rm GR} \\ (695) \\ (3529) \\ (372{\rm Y} \\ (711) \\ (735{\rm Y} \ (735{\rm Y} \$	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703 701, 702 D DIODE 701 X CRYS 701 R RESIS 713 701~708 711 710 709 712	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT FRANSISTOR IC SN7490 2SC372 Zener WZ050 TAL HC-6/U 1MHz TOR CARBON FILM ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W	100µF 100µF 220µF N N Y 685 1005 1K5 1005 1K5 22K5 470K5
$\begin{array}{c} 608, 609\\ 612\\ 614\\ 601, 605, 606, 607, 610\\ 611\\ 604\\ 613\\ \hline \\ \hline$	" 2SK 2SA 2SE 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC 2SC	$\begin{array}{c} (19{\rm GR} \\ (695) \\ (3529) \\ (2372{\rm Y} \\ (711) \\ (735{\rm Y} \\ (255) \\ (555) $	625, 633 627, 632 M PB PRINT 1459 (A~Z) Q IC & T 703 701, 702 D DIODE 701 X CRYS 701 R RESIS 713 701~708 711 710 709 712 VR POTEI	16WV 16WV ARKER UNIT ED CIRCUIT BOARD MARKER CIRCUIT FRANSISTOR IC SN7490 2SC372 Zener WZ050 TAL HC-6/U 1MHz TOR CARBON FILM ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W	100μF 100μF 220μF

708	50WV	10PF	810,830,831,837,838,84	41 50WV	0.01µ
701	50WV	40PF	828, 829	50WV	
702, 703	50WV	1500PF	811,817,818,820~825		
CE	ERAMIC DISC			TYROL	
704, 705	50 W V	0.01µF	826	50WV	330P
	ECTROLYTIC		827	50WV	1000P
707	16 W V	$10 \mu F$	TAI	NTALUM	
· · ·			839, 840	25 WV	
	CAPACITOR			TROLYT	
	ECV-1ZW 50×40	50PF	849, 850	16WV	- /
L INDUCTOR		0.50	832, 842	16WV	4.7µ]
and the second	EL0610-251K	250µH			
	M IF UNIT		L INDUCTOR	DI 001	0 0F415 0F0 1
$\frac{\mathbf{PB}}{1463} \frac{\mathbf{PRINTED}}{\mathbf{A} \sim \mathbf{Z}} \mathbf{FN}$	CIRCUIT BOARD		804		0-251K 250µI
1403 (A - Z) IW	I IF CIRCUIT		801~803, 806, 807 805		0-102K 1ml 0-202K 2ml
Q IC FET &	TRANSISTOR		803	EL001	0-202K 2ml
802	IC μA7031	HC	T TRANSFORM	IFR	
808	// TA7061		801, 802	R-12	4074
803	FET 2SK19		803		4861D
801,804~807,809~	811 2SC372	2Y	804		4861E
			805		3004
D DIODE			Sec. 101		
801, 802, 807~810	Si 1S1555				
803~806	Ge 1S188F	M	SSE	3 IF UNIT	
			PB PRINTED CIP		
X CRYSTAL			1462 (A \sim Z) SSB	IF CIRCI	UIT
801	HC-18/U	10.245MHz			
00000			Q IC FET & TF		
CF CERAMIC			902	IC	TA7045M
802	CFM 455E(F	•)	903, 906	FET	2SK19GR
803	10.7MF-BR		904, 905		2SC373
D DECICTOR			901		2SC784R
R RESISTOR	RBON		907, 908		2SC1000GR
804, 805, 826	1/4 W	100 Ω	D DIODE		
825, 827, 837	1/4 W	220 Ω	901~903, 912, 913	C :	10100
824	1/4 W	470 Ω	901~903, 912, 913 910	Si Ge	1S1555 1S188FM
803, 833, 842	1/4 W	560 Ω	904~907,909	G.B	1S1007
808, 816, 819, 828, 82		1KΩ	911	Zener	WZ110
836, 846, 847	, , , , , , , , , , , , , , , , , , , ,	111.00	511	Zeller	W 2110
809	$\frac{1}{4}$ W	1.5KΩ	XF CRYSTAL FI	ITER	
839, 840	1⁄4 W	2.2KΩ	901	XF-10A	
		3.3K Ω			
811, 813, 814, 821, 84					
, , , , , ,			R RESISTOR		
849~856		4.7K Ω	R RESISTOR CARB	ON FILM	I
849~856 801, 830, 831, 835, 84		4.7KΩ 5.6KΩ		ON FILM	
811, 813, 814, 821, 84 849 ~ 856 801, 830, 831, 835, 84 822, 838 802	$14 \frac{1}{4}W$		CARB		100 \$
849~856 801, 830, 831, 835, 84 822, 838 802	44 ¹ / ₄ W ¹ / ₄ W	5.6KΩ	CARB 909, 912, 914, 915, 919,	¼ W	100\$
849~856 801, 830, 831, 835, 84 822, 838 802 815, 845 823, 834, 841	44 ½W ¼W ¼W	5.6KΩ 10KΩ	CARB 909, 912, 914, 915, 919, 932, 933, 939, 940		
849~856 801, 830, 831, 835, 84 822, 838 802 815, 845 823, 834, 841 820, 832	44 ½W ½W ½W ½W	5.6KΩ 10KΩ 15KΩ	CARB 909, 912, 914, 915, 919, 932, 933, 939, 940 926, 927	1/4 W	100 s 270 s
849 ~ 856 801, 830, 831, 835, 84 822, 838 802 815, 845 823, 834, 841 820, 832 848	44 ½W ½W ½W ½W ½W	5.6KΩ 10KΩ 15KΩ 22KΩ	CARB 909, 912, 914, 915, 919, 932, 933, 939, 940 926, 927 917, 944	$\frac{\frac{1}{4}W}{\frac{1}{4}W}$	100 s 270 s 470 s
849 ~ 856 801, 830, 831, 835, 84 822, 838 802 815, 845 823, 834, 841 820, 832 848	44 ½W ½W ½W ½W ½W ½W	5.6KΩ 10KΩ 15KΩ 22KΩ 47KΩ	CARB 909, 912, 914, 915, 919, 932, 933, 939, 940 926, 927 917, 944 901, 902, 927	1/4 W 1/4 W 1/4 W 1/4 W	100 s 270 s 470 s 560 s
849 ~ 856 801, 830, 831, 835, 84 822, 838 802 815, 845 823, 834, 841 820, 832 848 806, 807, 810	44 ½W ½W ½W ½W ½W ½W ½W	5.6KΩ 10KΩ 15KΩ 22KΩ 47KΩ 56KΩ	CARB 909, 912, 914, 915, 919, 932, 933, 939, 940 926, 927 917, 944 901, 902, 927 934, 938, 946, 947, 905	1/4 W 1/4 W 1/4 W 1/4 W	100 s 270 s 470 s 560 s
849 ~ 856 801, 830, 831, 835, 84 822, 838 802 815, 845 823, 834, 841 820, 832 848 806, 807, 810 RS THERMIST	44 ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W	5.6KΩ 10KΩ 15KΩ 22KΩ 47KΩ 56KΩ	CARB 909, 912, 914, 915, 919, 932, 933, 939, 940 926, 927 917, 944 901, 902, 927 934, 938, 946, 947, 905 911, 913, 912 929 908, 910, 918, 930, 945	1/4 W	100 s 270 s 470 s 560 s 1 K s
849 ~ 856 801, 830, 831, 835, 84 822, 838 802 815, 845 823, 834, 841 820, 832 848 806, 807, 810 RS THERMIST	44 ½W ½W ½W ½W ½W ½W ½W ½W	5.6KΩ 10KΩ 15KΩ 22KΩ 47KΩ 56KΩ	CARB 909, 912, 914, 915, 919, 932, 933, 939, 940 926, 927 917, 944 901, 902, 927 934, 938, 946, 947, 905 911, 913, 912 929 908, 910, 918, 930, 945 925	1/4 W	100 s 270 s 470 s 560 s 1 K s
849~856 801, 830, 831, 835, 84 822, 838 802 815, 845 823, 834, 841 820, 832 848 806, 807, 810 RS THERMIST 801	44 ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W	5.6KΩ 10KΩ 15KΩ 22KΩ 47KΩ 56KΩ	CARB 909, 912, 914, 915, 919, 932, 933, 939, 940 926, 927 917, 944 901, 902, 927 934, 938, 946, 947, 905 911, 913, 912 929 908, 910, 918, 930, 945 925 903, 904, 942	1/4 W	100 s 270 s 470 s 560 s 1 K s 1.8K s 2.2K s
849 ~ 856 801, 830, 831, 835, 84 822, 838 802 815, 845 823, 834, 841 820, 832 848 806, 807, 810 RS THERMIST 801 C CAPACITO	44 ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W %DT-250	5.6KΩ 10KΩ 15KΩ 22KΩ 47KΩ 56KΩ	CARB 909, 912, 914, 915, 919, 932, 933, 939, 940 926, 927 917, 944 901, 902, 927 934, 938, 946, 947, 905 911, 913, 912 929 908, 910, 918, 930, 945 925 903, 904, 942 935, 936	1/4 W	100 s 270 s 470 s 560 s 1 k s 2 . 2 k s 2 . 7 k s
849~856 801, 830, 831, 835, 84 822, 838 802 815, 845 823, 834, 841 820, 832 848 806, 807, 810 RS THERMIST 801 C CAPACITO DII	44 ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W ^C OR SDT-250 R PPED	5.6KΩ 10KΩ 15KΩ 22KΩ 47KΩ 56KΩ 100KΩ	CARB 909, 912, 914, 915, 919, 932, 933, 939, 940 926, 927 917, 944 901, 902, 927 934, 938, 946, 947, 905 911, 913, 912 929 908, 910, 918, 930, 945 925 903, 904, 942 935, 936 906	1/4 W	100 s 270 s 470 s 560 s 1 k s 2 . 2 k s 2 . 7 k s 3 . 3 k s 4 . 7 k s 6 . 8 k s
849~856 801, 830, 831, 835, 84 822, 838 802 815, 845 823, 834, 841 820, 832 848 806, 807, 810 RS THERMIST 801 C CAPACITO DI1 812	44 ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W 50R SDT-250 R PPED 50WV	5.6KΩ 10KΩ 15KΩ 22KΩ 47KΩ 56KΩ 100KΩ	CARB 909, 912, 914, 915, 919, 932, 933, 939, 940 926, 927 917, 944 901, 902, 927 934, 938, 946, 947, 905 911, 913, 912 929 908, 910, 918, 930, 945 925 903, 904, 942 935, 936 906 941	1/4 W	100 s 270 s 470 s 560 s 1 k s 2 . 2 k s 2 . 7 k s 3 . 3 k s 4 . 7 k s 6 . 8 k s 10 k s
849~856 801, 830, 831, 835, 84 822, 838 802 815, 845 823, 834, 841 820, 832 848 806, 807, 810 RS THERMIST 801 C CAPACITO DII 812 806, 807	44 ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W 50 T-250 R PPED 50 W V 50 W V	5.6KΩ 10KΩ 15KΩ 22KΩ 47KΩ 56KΩ 100KΩ 100KΩ	CARB 909, 912, 914, 915, 919, 932, 933, 939, 940 926, 927 917, 944 901, 902, 927 934, 938, 946, 947, 905 911, 913, 912 929 908, 910, 918, 930, 945 925 903, 904, 942 935, 936 906 941 920, 924, 943	1/4 W	100 s 270 s 470 s 560 s 1 k s 2 . 2 k s 2 . 7 k s 3 . 3 k s 4 . 7 k s 6 . 8 k s 10 k s 2 . 2 k s
849~856 801, 830, 831, 835, 84 822, 838 802 815, 845 823, 834, 841 820, 832 848 806, 807, 810 RS THERMIST 801 C CAPACITO DI1 812 806, 807 833	44 ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W ² /4W ² /4W ² /4W ² /4W ² /4W ² /250 R PPED 50WV 50WV 50WV	5.6KΩ 10KΩ 15KΩ 22KΩ 47KΩ 56KΩ 100KΩ 100KΩ 15PF 30PF 40PF	CARB 909, 912, 914, 915, 919, 932, 933, 939, 940 926, 927 917, 944 901, 902, 927 934, 938, 946, 947, 905 911, 913, 912 929 908, 910, 918, 930, 945 925 903, 904, 942 935, 936 906 941 920, 924, 943 907	1/4 W	100 s 270 s 470 s 560 s 1 k s 2 . 2 k s 2 . 7 k s 3 . 3 k s 4 . 7 k s 6 . 8 k s 10 k s 2 . 2 k s 2 . 7 k s 2 . 7 k s 2 . 7 k s 2 . 7 k s
849~856 801, 830, 831, 835, 84 822, 838 802 815, 845 823, 834, 841 820, 832 848 806, 807, 810 RS THERMIST 801 C CAPACITO DII 812 806, 807 833 809, 835, 843	44 ¼W ¼W ¼W ¼W ¼W ¼W ¼W ½W * * * * * * * * * * * * * * * * * * *	5.6KΩ 10KΩ 15KΩ 22KΩ 47KΩ 56KΩ 100KΩ 100KΩ 15PF 30PF 40PF 100PF	CARB 909, 912, 914, 915, 919, 932, 933, 939, 940 926, 927 917, 944 901, 902, 927 934, 938, 946, 947, 905 911, 913, 912 929 908, 910, 918, 930, 945 925 903, 904, 942 935, 936 906 941 920, 924, 943 907 937	1/4 W	100 s 270 s 470 s 560 s 1 k s 2 . 2 k s 2 . 7 k s 3 . 3 k s 4 . 7 k s 6 . 8 k s 10 k s 2 . 2 k s 2 . 7 k s 5 6 k s
849~856 801, 830, 831, 835, 84 822, 838 802 815, 845 823, 834, 841 820, 832 848 806, 807, 810 RS THERMIST 801 C CAPACITO DII 812 806, 807 833 809, 835, 843 801	44 ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W % FOR SDT-250 R PPED 50WV 50WV 50WV 50WV 50WV	5.6KΩ 10KΩ 15KΩ 22KΩ 47KΩ 56KΩ 100KΩ 100KΩ 15PF 30PF 40PF 100PF 200PF	CARB 909, 912, 914, 915, 919, 932, 933, 939, 940 926, 927 917, 944 901, 902, 927 934, 938, 946, 947, 905 911, 913, 912 929 908, 910, 918, 930, 945 925 903, 904, 942 935, 936 906 941 920, 924, 943 907 937 916, 931	1/4 W	100 s 270 s 470 s 560 s 1 k s 2 . 2 k s 2 . 7 k s 3 . 3 k s 4 . 7 k s 6 . 8 k s 10 k s 22 k s 27 k s 56 k s 100 k s
849~856 801, 830, 831, 835, 84 822, 838 802 815, 845 823, 834, 841 820, 832 848 806, 807, 810 RS THERMIST 801 C CAPACITO DII 812 806, 807 833 809, 835, 843 801 834	44 ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W %W %W %OR SDT-250 % PPED 50WV 50WV 50WV 50WV 50WV 50WV 50WV	5.6KΩ 10KΩ 15KΩ 22KΩ 47KΩ 56KΩ 100KΩ 100KΩ 15PF 30PF 40PF 100PF	CARB 909, 912, 914, 915, 919, 932, 933, 939, 940 926, 927 917, 944 901, 902, 927 934, 938, 946, 947, 905 911, 913, 912 929 908, 910, 918, 930, 945 925 903, 904, 942 935, 936 906 941 920, 924, 943 907 937	1/4 W	100 s 270 s 470 s 560 s 1 k s 2 . 2 k s 2 . 7 k s 3 . 3 k s 4 . 7 k s 6 . 8 k s 10 k s 2 . 2 k s 2 . 7 k s 5 6 k s
849~856 801, 830, 831, 835, 84 822, 838 802 815, 845 823, 834, 841 820, 832 848 806, 807, 810 RS THERMIST 801 C CAPACITO DII 812 806, 807 833 809, 835, 843 801 834 CEI	44 1/4 W 1/4 W	5.6KΩ 10KΩ 15KΩ 22KΩ 47KΩ 56KΩ 100KΩ 100KΩ 100F 30PF 300PF 300PF	CARB 909, 912, 914, 915, 919, 932, 933, 939, 940 926, 927 917, 944 901, 902, 927 934, 938, 946, 947, 905 911, 913, 912 929 908, 910, 918, 930, 945 925 903, 904, 942 935, 936 906 941 920, 924, 943 907 937 916, 931 923	1/4 W 1/4 W	100 s 270 s 470 s 560 s 1 k s 2 . 2 k s 2 . 7 k s 3 . 3 k s 4 . 7 k s 6 . 8 k s 10 k s 22 k s 27 k s 56 k s 100 k s
849~856 801, 830, 831, 835, 84 822, 838 802 815, 845 823, 834, 841 820, 832 848 806, 807, 810 RS THERMIST 801 C CAPACITO DI1 812 806, 807 833 809, 835, 843 801 834 CEI 844	44 1/4 W 1/4 W	5.6KΩ 10KΩ 15KΩ 22KΩ 47KΩ 56KΩ 100KΩ 100KΩ 100KΩ 100F 30PF 40PF 100PF 200PF 300PF 300PF	CARB 909, 912, 914, 915, 919, 932, 933, 939, 940 926, 927 917, 944 901, 902, 927 934, 938, 946, 947, 905 911, 913, 912 929 908, 910, 918, 930, 945 925 903, 904, 942 935, 936 906 941 920, 924, 943 907 937 916, 931 923 RS THERMISTOR	1/4 W 1/4 W	100 s 270 s 470 s 560 s 1 k s 2 . 2 k s 2 . 2 k s 2 . 7 k s 3 . 3 k s 4 . 7 k s 6 . 8 k s 10 k s 22 k s 27 k s 56 k s 100 k s 470 k s
849~856 801, 830, 831, 835, 84 822, 838 802 815, 845 823, 834, 841 820, 832 848 806, 807, 810 RS THERMIST 801 C CAPACITO DII 812 806, 807 833 809, 835, 843 801 834 CEI	44 1/4 W 1/4 W	5.6KΩ 10KΩ 15KΩ 22KΩ 47KΩ 56KΩ 100KΩ 100KΩ 100F 30PF 300PF 300PF	CARB 909, 912, 914, 915, 919, 932, 933, 939, 940 926, 927 917, 944 901, 902, 927 934, 938, 946, 947, 905 911, 913, 912 929 908, 910, 918, 930, 945 925 903, 904, 942 935, 936 906 941 920, 924, 943 907 937 916, 931 923	1/4 W 1/4 W	100 s 270 s 470 s 560 s 1 k s 2 . 2 k s 2 . 2 k s 2 . 7 k s 3 . 3 k s 4 . 7 k s 6 . 8 k s 10 k s 22 k s 27 k s 56 k s 100 k s 470 k s

938 16WV 10μF 1103, 1104 Ge	GR 2Y 1S1555 1S188FN 1S1007 1S2687 0MHz 5MHz 5MHz 3MHz	
902 EVL-SOAA-00B53 5KB 1011 $16WV$ C CAPACITOR RL RELAY 915 50WV 10PF 916 50WV 20PF 916 50WV 100PF CERAMIC DISC PB PRINTED CIRCUIT BOARD 903.902,929,933 903.905,907,908,913,914 50WV 0.047 μ F Q IC FET & TRANSISTOR 932 50WV 0.047 μ F Q IC FET & TRANSISTOR 933.937 50WV 0.047 μ F 1104 IC LD-30 934.937 50WV 0.047 μ F 1101.1106, 1112.1117 Si 936 50WV 0.047 μ F DODDE 930.939 16WV 1 μ F 1101.1106, 1112.1117 Si 936 50WV 0.047 μ F DOIODE 930, 939 16WV 1 μ F 1101, 1105, 1106, 1112.21117 Si 934, 935, 922 16WV 1 μ F 1101, 1105, 1106, 1112.2117 Si Paractor 921 35WV 0.1 μ F 1101 HC-18/U 10.70	100µH 01 GR 2Y 1S1555 1S188FN 1S1007 1S2687 0MHz 5MHz 5MHz 3MHz	
DIPPED MICA 1001 LZ-2G 915 $50WV$ $10PF$ 916 $50WV$ $20PF$ 916 $50WV$ $100PF$ 917 $CERAMIC DISC$ PB PRINTED CIRCUIT BOARD 901, 902, 909 - 911, 906 $50WV$ $0.01\muF$ 1460 (A~Z) 903 - 905, 907, 908, 913, 914 50WV $0.01\muF$ 1460 (A~Z) MIC AMP CIRCUIT 937 $50WV$ $0.047\muF$ Q IC FET & TRANSISTOR 938 $50WV$ $0.02\muF$ $1101-1103, 1107, 1108$ $2SC37$ 931, 937 $50WV$ $0.047\muF$ $1101-1103, 1107, 1108$ $2SC37$ 934 $16WV$ $10\muF$ $1101, 105, 1106, 1112-1117$ Si 938 $16WV$ $10\muF$ $1101, 105, 1106, 1112-1117$ Si 938 $16WV$ $10\muF$ $1108 \sim 1111$ $G.B$ 934, 935, 922 $16WV$ $10\muF$ 1102 $Varactor$ 921 $35WV$ $0.1\muF$ 1102 $HC-18/U$ 10.700 1001	GR 2Y 1S1555 1S188FN 1S1007 1S2687 0MHz 5MHz 5MHz 3MHz	
DIPPED MICA 1001 LZ-2G 915 $50WV$ $10PF$ 916 $50WV$ $20PF$ 916 $50WV$ $100PF$ MIC AMP UNIT 901, 902, 909 - 911, 906 $50WV$ $0.01\muF$ 1460 (A~Z) MIC AMP CIRCUIT 917, 918, 920, 923, 929, 933 $903 - 905, 907, 908, 913, 914$ $50WV$ $0.01\muF$ 1460 (A~Z) MIC AMP CIRCUIT 917, 918, 920, 923, 929, 933 $903 - 905, 907, 908, 913, 914$ $50WV$ $0.047\muF$ Q IC FET & TRANSISTOR 938 $50WV$ $0.047\muF$ $1101 - 1103, 1107, 1108$ $2SC37$ 931, 937 $50WV$ $0.047\muF$ $1101 - 1103, 1107, 1108$ $2SC37$ 938 $16WV$ $1\muF$ $1101, 1105, 1106, 1112 - 1117$ Si 938, 935, 922 $16WV$ $1\muF$ $1108 - 1111$ $G.B$ 934, 935, 922 $16WV$ $1\muF$ 1102 $Varactor$ 921 $35WV$ $0.1\muF$ 1102 $Varactor$ 901 ECV-12W 50×40 $50PF$ 1101 </td <td>GR 2Y 1S1555 1S188FN 1S1007 1S2687 0MHz 5MHz 5MHz 3MHz</td>	GR 2Y 1S1555 1S188FN 1S1007 1S2687 0MHz 5MHz 5MHz 3MHz	
915 50 WV 10 PF 912 50 WV 20 PF 916 50 WV 100 PF MIC AMP UNIT 917 918, 90, 923, 929, 933 PB PRINTED CIRCUIT BOARD 903 \sim 905, 907, 908, 913, 914 50 WV 0.047 μ F Q IC FET & TRANSISTOR 932 \sim 905, 907, 908, 913, 914 50 WV 0.047 μ F Q IC FET & TRANSISTOR 933 \sim 905, 907, 908, 913, 914 50 WV 0.047 μ F Q IC FET & TRANSISTOR 934 936 \sim 50 WV 0.02 μ F 1106, 1106 FET 25 K19 936 50 WV 0.02 μ F 1101 \sim 1103, 1107, 1108 25 C37 931, 937 50 WV 0.047 μ F DIODE 936, 939 16 WV 1 μ F 1101 \sim 1103, 1104 Ge 938 16 WV 1 μ F 1103, 1104 Ge 934, 935, 922 16 WV 0.1 μ F 1102 Varactor 921 35 WV 0.1 μ F 1002 Varactor 901 ECV-1ZW 50 × 40 50 PF 1101 HC-18/U 10.700 901 EL0610 - 251 K 250 μ H	GR 2Y 1S1555 1S188FN 1S1007 1S2687 0MHz 5MHz 5MHz 3MHz	
912 50 WV 20 PF 916 50 WV 100 PF MIC AMP UNIT 903 903 903 903 9104 1460 (A~Z) MIC AMP CIRCUIT 903 903 903 904 9104 IC LD-30 932 50 WV 0.047 μ F 1105, 1106 FET 25K19 936 50 WV 0.02 μ F 1101 1103, 1107, 1108 25C37 931, 937 50 WV 0.047 μ F 1101 1103, 1107, 1108 25C37 936 50 WV 0.047 μ F 1101 1103, 1107, 1108 25C37 931, 937 50 WV 0.047 μ F 1103, 1104 Ge 938 16 WV 1 μ F 1103, 1104 Ge 938, 932 16 WV 1 μ F 1108 ~ 1111 G. B 931, 937 35 WV 0.1 μ F 1108 ~ 1111 G. B 938 16 WV 1 μ F 1108 ~ 1111 G. B 931 935 ψ 0.1 μ F 1103 HC-18/U 10.700 L INDUCTOR I102	GR 2Y 1S1555 1S188FN 1S1007 1S2687 0MHz 5MHz 5MHz 3MHz	
CERAMIC DISC PB PRINTED CIRCUIT BOARD 901, 902, 909 ~ 911, 906 50WV 0.01μ F 1460 (A~Z) MIC AMP CIRCUIT 917, 918, 920, 923, 929, 933 932 0.047 µF Q IC FET & TRANSISTOR 903 ~ 905, 907, 908, 913, 914 50WV $0.047 µF$ Q IC FET & TRANSISTOR 932 50WV $0.047 µF$ 1104 IC LD-30 936 50WV $0.02 µF$ 1101~1103, 1107, 1108 2SC37 931, 937 50WV $0.047 µF$ D DIODE 930 ~ 939 16WV $1.0µF$ 1101, 1105, 1106, 1112~1117 Si 938 16WV $1.0µF$ 1108~1111 G.B 934, 935, 922 16WV $1.0µF$ 1102 Varactor 921 35WV $0.1µF$ 1102 HC-18/U 10.700 L INDUCTOR 1102 HC-18/U 10.700 901 EL0610-251K 250µH 1103 HC-18/U 10.700 903 R-12 4074 R	GR 2Y 1S1555 1S188FN 1S1007 1S2687 0MHz 5MHz 5MHz 3MHz	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	GR 2Y 1S1555 1S188FN 1S1007 1S2687 0MHz 5MHz 5MHz 3MHz	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	GR 2Y 1S1555 1S188FN 1S1007 1S2687 0MHz 5MHz 5MHz 3MHz	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	GR 2Y 1S1555 1S188FN 1S1007 1S2687 0MHz 5MHz 5MHz 3MHz	
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	GR 2Y 1S1555 1S188FN 1S1007 1S2687 0MHz 5MHz 5MHz 3MHz	
932 $50WV$ 0.0047μ F $1105, 1106$ FET $2SK19$ 936 $50WV$ 0.02μ F $1101 - 1103, 1107, 1108$ $2SC37$ 931, 937 $50WV$ 0.047μ F D D ELECTROLYTIC D DIODE 930, 939 $16WV$ 1μ F $1101, 1105, 1106, 1112 - 1117$ Si 938 $16WV$ 1μ F $1103, 1104$ Ge 934, 935, 922 $16WV$ 47μ F $1108 - 1111$ G.B TANTALUM 1102 $Varactor$ 921 $35WV$ 0.1μ F $I102$ $Varactor$ 901 ECV-12W 50×40 $50PF$ 1101 HC-18/U 10.700 901 EL0610-251K 250μ H 1103 HC-18/U 10.698 901, 902 R-12 4074 R RESISTOR 901, 902 R-12 4073 CARBON FILM 903 R-12 4073 $CARBON FILM$ 904 <th cols<="" td=""><td>GR 2Y 1S1555 1S188FN 1S1007 1S2687 0MHz 5MHz 5MHz 3MHz</td></th>	<td>GR 2Y 1S1555 1S188FN 1S1007 1S2687 0MHz 5MHz 5MHz 3MHz</td>	GR 2Y 1S1555 1S188FN 1S1007 1S2687 0MHz 5MHz 5MHz 3MHz
936 $50WV$ 0.02μ F $1101-1103, 1107, 1108$ $2SC37$ 931, 937 $50WV$ 0.047μ F D DIODE 930, 939 $16WV$ 1μ F $1101, 1105, 1106, 1112-1117$ Si 938 $16WV$ 1μ F $1101, 1105, 1106, 1112-1117$ Si 938 $16WV$ 10μ F $1103, 1104$ Ge 934, 935, 922 $16WV$ 47μ F $1108 \sim 1111$ G.B TANTALUM 1102 Varactor 921 $35WV$ 0.1μ F TC CRYSTAL 901 ECV-12W 50×40 $50PF$ 1101 HC-18/U 10.700 L INDUCTOR 1102 HC-18/U 10.698 901 EL0610-251K 250μ H 1103 HC-18/U 10.699 T TRANSFORMER 903 R-12 4074 R RESISTOR 903 R-12 4073 CARBON FILM $1112, 1135, 1133, 1141, 1149, 1150, 1152, 1153$ PB PRINTED CIRCUIT BOARD $1114, 1102$ $¼W$ $1001 ~ 1003$ IC <th< td=""><td>2 Y 1 S1555 1 S188FN 1 S1007 1 S2687 0 MHz 5 MHz 5 MHz 3 MHz</td></th<>	2 Y 1 S1555 1 S188FN 1 S1007 1 S2687 0 MHz 5 MHz 5 MHz 3 MHz	
ELECTROLYTIC D DIODE 930,939 16WV 1μ F 1101,1105,1106,1112~1117 Si 938 16WV 10μ F 1103,1104 Ge 934,935,922 16WV 47μ F 1108~1111 G.B TANTALUM 1102 Varactor 921 35WV 0.1μ F 1102 Varactor 901 ECV-1ZW 50×40 50PF 1101 HC-18/U 10.700 L INDUCTOR 1102 HC-18/U 10.698 901 EL0610-251K 250 μ H 1103 HC-18/U 10.698 901,902 R-12 4074 R RESISTOR 901,902 R-12 4073 CARBON FILM 901,902 R-12 4073 CARBON FILM 901 EURST UNIT 1103,1141,1148,1149,1150,1152,1153 1133,1141,1148,1149,1150,1152,1153 901 R-12 4073 CARBON FILM 901,902 R-12 4074 R 901 INDUCTOR 1103,11	1 S 188 F M 1 S 1007 1 S 2687 0 MHz 5 MHz 5 MHz 3 MHz	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	1 S 188 F M 1 S 1007 1 S 2687 0 MHz 5 MHz 5 MHz 3 MHz	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	1 S 188 F M 1 S 1007 1 S 2687 0 MHz 5 MHz 5 MHz 3 MHz	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	1 S1007 1 S2687 0MHz 5MHz 5MHz 3MHz	
TANTALUM 1102 Varactor 921 $35WV$ $0.1\muF$ TC TRIMMER CAPACITOR X CRYSTAL 901 ECV-1ZW 50×40 $50PF$ 1101 HC-18/U 10.700 L INDUCTOR 1102 HC-18/U 10.700 901 EL0610-251K 250μ H 1103 HC-18/U 10.700 901 EL0610-251K 250μ H 1103 HC-18/U 10.698 901, 902 R-12 4074 R RESISTOR 903 R-12 4074 R RESISTOR 903 R-12 4073 CARBON FILM 904 I101, 1105, 1121, 1124, 1129 $\frac{1}{4}W$ 1101, 1105, 1121, 1124, 1137 $\frac{1}{4}W$ 1101, 1105, 1133, 1141, 1148, 1149, 1150, 1152, 1153 11133, 1141, 1148, 1149, 1150, 1152, 1153 903 R-12 4073 CARBON FILM 904 PB PRINTED CIRCUIT BOARD 1114, 1102 $\frac{1}{4}W$ 1461 (A~Z) TONE BURST CIRCUIT 1106, 1113, 1125, 1127, 1145<	1 S2687 0MHz 5MHz 5MHz 3MHz	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	0MHz 5MHz 5MHz 3MHz	
TC TRIMMER CAPACITOR X CRYSTAL 901 $ECV-1ZW 50 \times 40$ 50PF 1101 $HC-18/U$ 10.700 L INDUCTOR 1102 $HC-18/U$ 10.701 901 $EL0610-251K$ 250μ H 1103 $HC-18/U$ 10.698 1004 HC-18/U 10.698 1104 HC-18/U 10.698 T TRANSFORMER CARBON FILM HC-18/U 10.699 T TRANSFORMER CARBON FILM 1001.0105, 1121, 1124, 1129 $¼$ W 903 R-12 4073 CARBON FILM 903 R-12 4073 CARBON FILM 903 R-12 4073 CARBON FILM 904 TONE BURST UNIT 1101,1105,1121,1124,1129 $¼$ W 905 PRINTED CIRCUIT BOARD 1112,1135,1136,1138,1142,1137 $¼$ W 906 IC & FET 1106,1113,1125,1127,1145 $¼$ W 901 ~ 1003 IC TP4011AN 1143 $¼$ W 9005 TP4027AN 1116,1140,1144 <th< td=""><td>5MHz 5MHz 3MHz</td></th<>	5MHz 5MHz 3MHz	
901 ECV-1ZW 50×40 50PF 1101 HC-18/U 10.700 L INDUCTOR 1102 HC-18/U 10.701 901 EL0610-251K 250µH 1103 HC-18/U 10.698 901 OLO610-251K 250µH 1103 HC-18/U 10.698 T TRANSFORMER 1104 HC-18/U 10.699 903 R-12 4074 R RESISTOR 903 R-12 4073 CARBON FILM 903 R-12 4073 CARBON FILM 904 TONE BURST UNIT 1101,1105,1121,1124,1129 ¼W 905 TONE BURST UNIT 1112,1135,1136,1138,1142,1137 ¼W 904 IO6,1113,1125,1127,1145 ¼W 905 TONE BURST CIRCUIT 1106,1113,1125,1127,1145 ¼W 901~1003 IC TP4027AN 1116,1140,1144 ¼W 905 TP4049AN 1139 ¼W	5MHz 5MHz 3MHz	
L INDUCTOR 1102 HC-18/U 10.701 901 EL0610-251K 250µH 1103 HC-18/U 10.698 1104 HC-18/U 10.698 1104 HC-18/U 10.699 T TRANSFORMER 1104 HC-18/U 10.699 903 R-12 4074 R RESISTOR 903 R-12 4073 CARBON FILM 101,1105,1121,1124,1129 ¼W 1133,1141,1148,1149,1150,1152,1153 TONE BURST UNIT 1112,1135,1136,1138,1142,1137 ¼W PB PRINTED CIRCUIT BOARD 1114,1102 ¼W 1461 (A~Z) TONE BURST CIRCUIT 1106,1113,1125,1127,1145 ¼W 1461 (A~Z) TONE BURST CIRCUIT 1106,1113,1125,1127,1145 ¼W 1001~1003 IC TP4011AN 1143 ¼W 1005 TP4027AN 1116,1140,1144 ¼W 1004 TP4049AN 1139 ¼W	5MHz 5MHz 3MHz	
Ind HC-18/U 10.699 T TRANSFORMER Resistor 901, 902 R-12 4074 R RESISTOR 903 R-12 4073 CARBON FILM 1101,1105,1121,1124,1129 ¼W 1133,1141,1148,1149,1150,1152,1153 TONE BURST UNIT 1112,1135,1136,1138,1142,1137 ¼W PB PRINTED CIRCUIT BOARD 1114,1102 ¼W 1461 (A~Z) TONE BURST CIRCUIT 1106,1113,1125,1127,1145 ¼W 1461 (A~Z) TONE BURST CIRCUIT 1106,1113,1125,1127,1145 ¼W 1001~1003 IC TP4011AN 1143 ¼W 1005 TP4027AN 1116,1140,1144 ¼W 1004 TP4049AN 1139 ¼W	3MHz	
T TRANSFORMER 901, 902 R-12 4074 R RESISTOR 903 R-12 4073 CARBON FILM 903 R-12 4073 CARBON FILM 1101,1105,1121,1124,1129 ¼W 1133,1141,1148,1149,1150,1152,1153 TONE BURST UNIT 1112,1135,1136,1138,1142,1137 ¼W PB PRINTED CIRCUIT BOARD 1114,1102 ¼W 1461 (A~Z) TONE BURST CIRCUIT 1106,1113,1125,1127,1145 ¼W 1461 (A~Z) TONE BURST CIRCUIT 1106,1113,1125,1127,1145 ¼W 1001~1003 IC TP4011AN 1143 ¼W 1005 TP4027AN 1116,1140,1144 ¼W 1004 TP4049AN 1139 ¼W		
901, 902 R-12 4074 R RESISTOR 903 R-12 4073 CARBON FILM 1101, 1105, 1121, 1124, 1129 ½ W 1101, 1105, 1121, 1124, 1129 ½ W 11133, 1141, 1148, 1149, 1150, 1152, 1153 TONE BURST UNIT 1112, 1135, 1136, 1138, 1142, 1137 ½ W PB PRINTED CIRCUIT BOARD 1114, 1102 ½ W 1461 (A~Z) TONE BURST CIRCUIT 1106, 1113, 1125, 1127, 1145 ½ W 1117, 1122, 1123, 1147, 1151 Q IC & FET 1104, 1128 ½ W 1001~1003 IC TP4011AN 1143 ½ W 1005 TP4027AN 1116, 1140, 1144 ½ W 1004 TP4049AN 1139 ½ W	100	
903 R-12 4073 CARBON FILM 1101,1105,1121,1124,1129 ¼W 1133,1141,1148,1149,1150,1152,1153 TONE BURST UNIT 1112,1135,1136,1138,1142,1137 PB PRINTED CIRCUIT BOARD 1114,1102 ¼W 1461 (A~Z) TONE BURST CIRCUIT 1106,1113,1125,1127,1145 ¼W 1117,1122,1123,1147,1151 ¼W 1001~1003 IC TP4027AN 1116,1140,1144 1004 TP4049AN	100/	
1101,1105,1121,1124,1129 ¼W 1133,1141,1148,1149,1150,1152,1153 TONE BURST UNIT 1112,1135,1136,1138,1142,1137 PB PRINTED CIRCUIT BOARD 1114,1102 1461 (A~Z) TONE BURST CIRCUIT 1106,1113,1125,1127,1145 I 1117,1122,1123,1147,1151 ¼W I 1104,1128 ¼W 1001~1003 IC TP4011AN 1143 1005 TP4027AN 1116,1140,1144 ¼W 1004 TP4049AN 1139 ¼W	100/	
Instruction	100 9	
TONE BURST UNIT 1112,1135,1136,1138,1142,1137 ¼W PB PRINTED CIRCUIT BOARD 1114,1102 ¼W 1461 (A~Z) TONE BURST CIRCUIT 1106,1113,1125,1127,1145 ¼W 1461 (A~Z) TONE BURST CIRCUIT 1106,1113,1125,1127,1145 ¼W Q IC & FET 1104,1128 ¼W 1001~1003 IC TP4011AN 1143 ¼W 1005 TP4027AN 1116,1140,1144 ¼W 1004 TP4049AN 1139 ¼W	1000	
1461 (A~Z) TONE BURST CIRCUIT 1106,1113,1125,1127,1145 ½W 1117,1122,1123,1147,1151 ½W Q IC & FET 1104,1128 ½W 1001~1003 IC TP4011AN 1143 ½W 1005 TP4027AN 1116,1140,1144 ½W 1004 TP4049AN 1139 ½W	2209	
Introduction Introduction<	4709	
Q IC & FET 1104, 1128 ½W 1001~1003 IC TP4011AN 1143 ½W 1005 TP4027AN 1116, 1140, 1144 ½W 1004 TP4049AN 1139 ½W	1K9	
1001~1003 IC TP4011AN 1143 ½W 1005 TP4027AN 1116, 1140, 1144 ½W 1004 TP4049AN 1139 ¼W	2.2Kg	
1005 TP4027AN 1116, 1140, 1144 ½ W 1004 TP4049AN 1139 ½ W	3.3K9 4.7K9	
1004 TP4049AN 1139 ¹ / ₄ W	5.6Ks	
	6.8Kg	
	10K9	
1115, ¹ / ₄ W	12K9	
D DIODE 1107, 1111 ¹ / ₄ W	22K	
1001~1003 Ge 1S188FM 1103 ¹ / ₄ W	27Kg	
R RESISTOR 1110, 1119 14W	33K9	
CARBON FILM 1109, 1126, 1130 ¹ / ₄ W	100Kg	
1014 $\frac{1}{4}$ W220 Ω VRPOTENTIOMETER1013 $\frac{1}{4}$ W10K Ω 1102EVL-SOAA-00B32	3001	
$\frac{1013}{1015} \qquad \frac{1000}{1000} = \frac{1000}{1000} = 1000000000000000000000000000000000000$		
1010 $\frac{1}{4}$ W 100 H 00		
$\frac{1011}{1012} \qquad \frac{1}{4} \text{W} \qquad 820 \text{K} \Omega \qquad \text{C} \qquad \text{CAPACITOR}$		
1001~1005,1008~1010 ¼W 1MΩ DIPPED MICA		
1159 50WV	3P	
CARBON COMPOSITION 1158 50WV	10P	
1006, 1007 ¼W 2.2MΩ 1106	15P	
VR POTENTIOMETER 1146 50WV 1002, 1003 EVL-SOAA-00B15 100KB 1140, 1154~1156 50WV	20PI 30PI	
1002, 1003 EVL-SOAA-00B15 100KB 1140, 1154~1156 50WV 1001 EVL-SOAA-00B26 2MB 50WV	501-1	
1001 EVL-SOAA-00B26 2MB 50WV 1107, 1108, 1147 50WV	100PI	
C CAPACITOR 1148 50WV		
DIPPED MICA 1143 50WV	150PI	
1009 50WV 1000PF. 1110 50WV	200PI	
MYLAR 1126~1128 50WV		
1001,1002,1004,1005, 50WV 0.01µF CERAMIC DISC	200PI	
1007, 1010 1136 50WV	200PI 250PI 270PI	
	200PI 250PI 270PI	
TANTALUM 1101, 1102, 1104, 50WV 1002 25WU 0.22.E 1122 - 1125 1120 1141	200PI 250PI 270PI	
TANTALUM 1101, 1102, 1104, 50WV 1003 35WV 0.33μF 1133~1135, 1138, 1139, 1141, 1006, 1008 35WV 0.47μF 1142, 1144, 1145, 1149~1153	200PI 250PI 270PI	

	MYLAR		1203, 1	207, 1209	16 W V	10µF
1111, 1115, 11	16, 1122 50WV	$0.047 \mu F$				
	ELECTROLYTIC		TC	TRIMMER	CAPACITOR	
1114, 1117, 112	29,1131 16WV	$1 \mu F$	1201		$ECV-1ZW50 \times 4$	40 50PF
	21, 1123~1125, 16WV	10µF	1202-	1204	TSN-P-100DS	20PF
1130						
1120	16WV	$22 \mu F$	L	INDUCTOR		
1112, 1113	16WV	$47\mu F$		207		
1112, 1110	10 ** *	TIMI			209 #221020	
	MER CAPACITOR	0000	1211, 1		# 221021	
	ECV-1ZW 20×4			203		00 T
1101	$ECV-1ZW50\times4$	0 50PF	1210		EL0610-220K	22µH
L INDU				RELAY		
1101	# 221024		1201		LZ-2G D	C12 450 S
1107	EL0610-100K	10µH				
1106,1108,	EL0610-102K	1mH				
1109,1110,111	1.1112		State of the	VFO U	NIT	
			PB	PRINTED C	CIRCUIT BOARD	
			1465	$(A \sim Z)$ VF	O CIRCUIT	
T TRAN	SFORMER					
1101	R-12 #407	4	0	FET & TR	ANSISTOR	
1101	$R-12 \pm 407$ R-12 ± 407		1302	I ET OL IRA		19GR
1102	K-12 #407	J		202		
	£		1301, 1	1303	2SC:	0121
	BOOSTER UNIT	and the second second	R	RESISTOR		
	TED CIRCUIT BOARD				RBON FILM	
1470 $(A \sim Z)$	BOOSTER CIRCUIT			1311, 1312		100 \$
			1310		$\frac{1}{4}$ W	150 \$
Q TRAN	SISTOR		1306		$\frac{1}{4}$ W	470 \$
1201	BAM-20		1304		$\frac{1}{4}$ W	2.2KS
1202	BAM-40		1301		1/4 W	3.3KG
1000	1711/1 TV		1308		1/4 W	6.8KS
D DIOD	F		1308		1/4 W	15KS
		1	1309		1/4 W	18KS
1201, 1202	Si 10D	the second se				33KS
1205~1208	151		1303		1/4 W	
1203, 1204		88FM	1305		1⁄4 W	100KS
1209	Zener 1N4	/40				
			С	CAPACITOR	the second se	
	STOR			DIP	PED MICA	
CA	ARBON COMPOSITION		1318		50WV	2PF
	1⁄2 W	10 Ω	1302		50WV	20PF
1204		22 Ω	1313		50WV	39PF
	$\frac{1}{2}$ W		1010			
1201		56.0	1306		50WV	51PF
1201 1203	1/2 W	56 Ω 100 Ω	1306			
1201 1203 1205	1/2 W 1/2 W	100 Ω	1306 1311		50WV	68PF
1201 1203 1205 1202	1√2 W 1√2 W 1√2 W	100 Ω 330 Ω	1306 1311 1307		50WV 50WV	68PF 270PF
1201 1203 1205 1202 1206	<u>½</u> W ½2W ½2W ½2W	100 Ω 330 Ω 100 Κ Ω	1306 1311		50 W V 50 W V 50 W V	68PF
1201 1203 1205 1202 1206	1√2 W 1√2 W 1√2 W	100 Ω 330 Ω	1306 1311 1307 1310		50WV 50WV 50WV RAMIC DISC	68PF 270PF 470PF
1201 1203 1205 1202 1206 1207	1/2 W	100 Ω 330 Ω 100 Κ Ω	1306 1311 1307 1310 1308, 2	1309, 1312,	50 W V 50 W V 50 W V	68PF 270PF
1201 1203 1205 1202 1206 1207	½W	100 Ω 330 Ω 100ΚΩ 1ΜΩ	1306 1311 1307 1310	1309, 1312, 1316	50WV 50WV 50WV RAMIC DISC 50WV	68PF 270PF 470PF
1201 1203 1205 1202 1206 1207 VR POTE	1/2 W	100 Ω 330 Ω 100KΩ 1MΩ 10KB	1306 1311 1307 1310 1308, 2	1309, 1312, 1316	50WV 50WV 50WV RAMIC DISC 50WV CRAMIC TC	68PF 270PF 470PF 0.01μF
1201 1203 1205 1202 1206 1207 VR POTE 1201	½W	100 Ω 330 Ω 100KΩ 1MΩ	1306 1311 1307 1310 1308, 2	1309, 1312, 1316	50WV 50WV 50WV RAMIC DISC 50WV	68PF 270PF 470PF
1201 1203 1205 1202 1206 1207 VR POTE 1201	½W	100 Ω 330 Ω 100KΩ 1MΩ 10KB	1306 1311 1307 1310 1308, 2 1314~	1309, 1312, 1316	50WV 50WV 50WV RAMIC DISC 50WV CRAMIC TC	68PF 270PF 470PF 0.01μF
1201 1203 1205 1202 1206 1207 VR POTE 1201 1202	1/2 W ENTIOMETER EVL-SOAA-00B14 EVL-SOAA-00B54	100 Ω 330 Ω 100KΩ 1MΩ 10KB	1306 1311 1307 1310 1308, 2 1314 ~ 1303 1304	1309, 1312, 1316	50WV 50WV 50WV RAMIC DISC 50WV CRAMIC TC 500WV	68PF 270PF 470PF 0.01μF 5PF UJ
1201 1203 1205 1202 1206 1207 VR POTE 1201 1202	½W W EVL-SOAA-00B14 EVL-SOAA-00B54	100 Ω 330 Ω 100KΩ 1MΩ 10KB	1306 1311 1307 1310 1308, 2 1314 1303 1304 1301	1309, 1312, 1316	50 W V 50 W V 50 W V RAMIC DISC 50 W V CRAMIC TC 500 W V 500 W V 500 W V	68PF 270PF 470PF 0.01μF 5PF U. 10PF U. 20PF U.
1201 1203 1205 1202 1206 1207 VR POTE 1201 1202 C CAPA	½W ½CH ½CH ½CH ½D W W W W W W W W W W W W W W W <td>100 Ω 330 Ω 100KΩ 1MΩ 10KB 50KB</td> <td>1306 1311 1307 1310 1308, 2 1314 ~ 1303 1304</td> <td>1309, 1312, 1316 CF</td> <td>50 W V 50 W V 50 W V RAMIC DISC 50 W V CRAMIC TC 500 W V 500 W V 500 W V 500 W V</td> <td>68PF 270PF 470PF 0.01μF 5PF U. 10PF U. 20PF U.</td>	100 Ω 330 Ω 100KΩ 1MΩ 10KB 50KB	1306 1311 1307 1310 1308, 2 1314 ~ 1303 1304	1309, 1312, 1316 CF	50 W V 50 W V 50 W V RAMIC DISC 50 W V CRAMIC TC 500 W V 500 W V 500 W V 500 W V	68PF 270PF 470PF 0.01μF 5PF U. 10PF U. 20PF U.
1201 1203 1205 1202 1206 1207 VR POTE 1201 1202 C CAPA 1216	½W ½COM W W W W W COM DIPPED MICA 50WV	100 Ω 330 Ω 100KΩ 1MΩ 10KB 50KB 2PF	1306 1311 1307 1310 1308, 2 1314 1303 1304 1301 1305	1309, 1312, 1316 CF	50WV 50WV 50WV RAMIC DISC 50WV CRAMIC TC 500WV 500WV 500WV 500WV 500WV 1C FEED THRU	68PF 270PF 470PF 0.01μF 5PF UJ 10PF UJ 20PF UJ 82PF NP
1201 1203 1205 1202 1206 1207 VR POTE 1201 1202 C CAPA 1216 1217, 1223	½W ½COM W MCITOR DIPPED MICA 50WV 50WV	100 Ω 330 Ω 100KΩ 1MΩ 10KB 50KB 2PF 5PF	1306 1311 1307 1310 1308, 2 1314 1303 1304 1301	1309, 1312, 1316 CF	50 W V 50 W V 50 W V RAMIC DISC 50 W V CRAMIC TC 500 W V 500 W V 500 W V 500 W V	68PF 270PF 470PF 0.01μF 5PF UJ 10PF UJ 20PF UJ
1201 1203 1205 1202 1206 1207 VR POTE 1201 1202 C CAPA 1216 1217, 1223 1201, 1205	½W MCITOR DIPPED MICA 50WV 50WV 50WV	100 Ω 330 Ω 100KΩ 1MΩ 10KB 50KB 2PF 5PF 10PF	1306 1311 1307 1310 1308, 2 1314 1303 1304 1301 1305 1317	1309, 1312, 1316 CF CERAM	50 W V 50 W V 50 W V RAMIC DISC 50 W V CRAMIC TC 500 W V 500 W V 500 W V 500 W V IC FEED THRU ECK-L1H102PE	68PF 270PF 470PF 0.01μF 5PF UJ 10PF UJ 20PF UJ 82PF NP
1201 1203 1205 1202 1206 1207 VR POTE 1201 1202 C CAPA 1216 1217, 1223 1201, 1205 1213 ~ 1215	½W MCITOR DIPPED MICA 50WV 50WV 50WV 50WV	100 Ω 330 Ω 100KΩ 1MΩ 10KB 50KB 2PF 5PF 10PF 20PF	1306 1311 1307 1310 1308, 2 1314 1303 1304 1301 1305 1317 VC	1309, 1312, 1316 CF CERAM	50 W V 50 W V 50 W V RAMIC DISC 50 W V CRAMIC TC 500 W V 500 W V 500 W V 500 W V 1C FEED THRU ECK-L1H102PE	68PF 270PF 470PF 0.01μF 5PF UJ 10PF UJ 20PF UJ 82PF NP
1201 1203 1205 1202 1206 1207 VR POTE 1201 1202 C CAPA 1216 1217, 1223 1201, 1205 1213 ~ 1215	½W MCITOR DIPPED MICA 50WV 50WV 50WV	100 Ω 330 Ω 100KΩ 1MΩ 10KB 50KB 2PF 5PF 10PF	1306 1311 1307 1310 1308, 2 1314 1303 1304 1301 1305 1317	1309, 1312, 1316 CF CERAM	50 W V 50 W V 50 W V RAMIC DISC 50 W V CRAMIC TC 500 W V 500 W V 500 W V 500 W V IC FEED THRU ECK-L1H102PE	68PF 270PF 470PF 0.01μF 5PF UJ 10PF UJ 20PF UJ 82PF NP
1201 1203 1205 1202 1206 1207 VR POTE 1201 1202 C CAPA 1216 1217, 1223 1201, 1205 1213 ~ 1215 1212	½W MCITOR DIPPED MICA 50WV 50WV 50WV 50WV	100 Ω 330 Ω 100KΩ 1MΩ 10KB 50KB 2PF 5PF 10PF 20PF	1306 1311 1307 1310 1308, 2 1314 1303 1304 1301 1305 1317 VC	1309, 1312, 1316 CF CERAM	50 W V 50 W V 50 W V RAMIC DISC 50 W V CRAMIC TC 500 W V 500 W V 500 W V 500 W V 1C FEED THRU ECK-L1H102PE	68PF 270PF 470PF 0.01μF 5PF UJ 10PF UJ 20PF UJ 82PF NP
1201 1203 1205 1202 1206 1207 VR POTE 1201 1202 C CAPA 1216 1217, 1223 1201, 1205 1213 ~ 1215 1212 1211	½W COMETER EVL-SOAA-00B54 ACITOR DIPPED MICA 50WV 50WV 50WV 50WV 50WV	100 Ω 330 Ω 100KΩ 1MΩ 10KB 50KB 2PF 5PF 10PF 20PF 39PF	1306 1311 1307 1310 1308, 2 1314 1303 1304 1301 1305 1317 VC	1309, 1312, 1316 CERAM VARIABLE	50 W V 50 W V 50 W V RAMIC DISC 50 W V CRAMIC TC 500 W V 500 W V 500 W V 500 W V 1C FEED THRU ECK-L1H102PE	68PF 270PF 470PF 0.01μF 5PF UJ 10PF UJ 20PF UJ 82PF NP
1201 1203 1205 1202 1206 1207 VR POTE 1201 1202 C CAPA 1216 1217, 1223 1201, 1205 1213 ~ 1215 1212 1211	½W SOWV 50WV 50WV 50WV 50WV	100 Ω 330 Ω 100KΩ 1MΩ 10KB 50KB 2PF 5PF 10PF 20PF 39PF 68PF	1306 1311 1307 1310 1308, 2 1314 1303 1304 1301 1305 1317 VC 1301 TC	1309, 1312, 1316 CERAM VARIABLE	50 W V 50 W V 50 W V RAMIC DISC 50 W V CRAMIC TC 500 W V 500 W V 500 W V 500 W V 1C FEED THRU ECK-L1H102PE CAPACITOR C512C	68PF 270PF 470PF 0.01μF 5PF UJ 10PF UJ 20PF UJ 82PF NP
1201 1203 1205 1202 1206 1207 VR POTE 1201 1202 C CAPA 1216 1217, 1223 1201, 1205 1213 ~ 1215 1212 1211 1206	½W EVL-SOAA-00B14 EVL-SOAA-00B54 ACITOR DIPPED MICA 50WV 50WV 50WV 50WV 50WV 50WV 50WV 50WV 50WV	100 Ω 330 Ω 100KΩ 1MΩ 10KB 50KB 2PF 5PF 10PF 20PF 39PF 68PF 100PF	1306 1311 1307 1310 1308, 2 1314 1303 1304 1301 1305 1317 VC 1301 VC 1301	1309, 1312, 1316 CERAM VARIABLE	50 W V 50 W V S0 W V RAMIC DISC 50 W V CRAMIC TC 500 W V 500 W V 500 W V 500 W V 1C FEED THRU ECK-L1H102PE CAPACITOR C512C CAPACITOR MC10P×2	68PF 270PF 470PF 0.01μF 5PF UJ 10PF UJ 20PF UJ 82PF NP
1201 1203 1205 1202 1206 1207 VR POTE 1201 1202 C CAPA 1216 1217, 1223 1201, 1205 1213 ~ 1215 1212 1211 1206 1202, 1204, 12	½W SOWV 50WV	100 Ω 330 Ω 100KΩ 1MΩ 10KB 50KB 2PF 5PF 10PF 20PF 39PF 68PF 100PF 0.001μF	1306 1311 1307 1310 1308, 2 1314 1303 1304 1301 1305 1317 VC 1301 TC	1309, 1312, 1316 CERAM VARIABLE	50 W V 50 W V 50 W V RAMIC DISC 50 W V CRAMIC TC 500 W V 500 W V 500 W V 500 W V 1C FEED THRU ECK-L1H102PE CAPACITOR C512C	68PF 270PF 470PF 0.01μF 5PF UJ 10PF UJ 20PF UJ 82PF NP
1201 1203 1205 1202 1206 1207 VR POTE 1201 1202 C CAPA 1216 1217, 1223 1201, 1205 1213 ~ 1215 1212 1211 1206 1202, 1204, 12	½W EVL-SOAA-00B14 EVL-SOAA-00B54 ACITOR DIPPED MICA 50WV	100 Ω 330 Ω 100KΩ 1MΩ 10KB 50KB 2PF 5PF 10PF 20PF 39PF 68PF 100PF	1306 1311 1307 1310 1308, 1 1314 1303 1304 1301 1305 1317 VC 1301 1301 1302	1309, 1312, 1316 CE CERAM VARIABLE TRIMMER	50 W V 50 W V S0 W V RAMIC DISC 50 W V CRAMIC TC 500 W V 500 W V 500 W V 500 W V 1C FEED THRU ECK-L1H102PE CAPACITOR C512C CAPACITOR MC10P×2	68PF 270PF 470PF 0.01μF 5PF UJ 10PF UJ 20PF UJ 82PF NP
1201 1203 1205 1202 1206 1207 VR POTE 1201 1202 C CAPA 1216 1217, 1223 1201, 1205 1213 ~ 1215 1212 1211 1206 1202, 1204, 12 1218 ~ 1220	1/2 W ENTIOMETER EVL-SOAA-00B14 EVL-SOAA-00B54 ACITOR DIPPED MICA 50WV X <td>100 Ω 330 Ω 100KΩ 1MΩ 10KB 50KB 2PF 5PF 10PF 20PF 39PF 68PF 100PF 0.001μF 0.01μF</td> <td>1306 1311 1307 1310 1308, 1 1314 1303 1304 1301 1305 1317 VC 1301 VC 1301 1302 L</td> <td>1309, 1312, 1316 CERAM VARIABLE</td> <td>50 W V 50 W V 50 W V RAMIC DISC 50 W V CRAMIC TC 500 W V 500 W V 500 W V 500 W V 1C FEED THRU ECK-L1H102PE CAPACITOR C512C CAPACITOR MC10P×2 KC-30P</td> <td>68PF 270PF 470PF 0.01μF 5PF UJ 10PF UJ 20PF UJ 82PF NP</td>	100 Ω 330 Ω 100KΩ 1MΩ 10KB 50KB 2PF 5PF 10PF 20PF 39PF 68PF 100PF 0.001μF 0.01μF	1306 1311 1307 1310 1308, 1 1314 1303 1304 1301 1305 1317 VC 1301 VC 1301 1302 L	1309, 1312, 1316 CERAM VARIABLE	50 W V 50 W V 50 W V RAMIC DISC 50 W V CRAMIC TC 500 W V 500 W V 500 W V 500 W V 1C FEED THRU ECK-L1H102PE CAPACITOR C512C CAPACITOR MC10P×2 KC-30P	68PF 270PF 470PF 0.01μF 5PF UJ 10PF UJ 20PF UJ 82PF NP
1201 1203 1205 1202 1206 1207 VR POTE 1201 1202 C CAPA 1216 1217, 1223 1201, 1205 1213 ~ 1215 1212 1211 1206 1202, 1204, 12 1218 ~ 1220	1/2 W ENTIOMETER EVL-SOAA-00B14 EVL-SOAA-00B54 ACITOR DIPPED MICA 50WV S0WV 50WV 50WV 50WV	100 Ω 330 Ω 100KΩ 1MΩ 10KB 50KB 2PF 5PF 10PF 20PF 39PF 68PF 100PF 0.001μF	1306 1311 1307 1310 1308, 1 1314 	1309, 1312, 1316 CE CERAM VARIABLE TRIMMER	50 W V 50 W V 50 W V RAMIC DISC 50 W V CRAMIC TC 500 W V 500 W V 500 W V 500 W V 1C FEED THRU ECK-L1H102PE CAPACITOR C512C CAPACITOR MC10P×2 KC-30P # 221025	68PF 270PF 470PF 0.01μF 5PF UJ 10PF UJ 20PF UJ 82PF NP 1000PF
1202 1206 1207 VR POTE 1201 1202	1/2 W ENTIOMETER EVL-SOAA-00B14 EVL-SOAA-00B54 ACITOR DIPPED MICA 50WV X <td>100 Ω 330 Ω 100KΩ 1MΩ 10KB 50KB 2PF 5PF 10PF 20PF 39PF 68PF 100PF 0.001μF 0.01μF</td> <td>1306 1311 1307 1310 1308, 1 1314 1303 1304 1301 1305 1317 VC 1301 VC 1301 1302 L</td> <td>1309, 1312, 1316 CE CERAM VARIABLE TRIMMER</td> <td>50 W V 50 W V 50 W V RAMIC DISC 50 W V CRAMIC TC 500 W V 500 W V 500 W V 500 W V 1C FEED THRU ECK-L1H102PE CAPACITOR C512C CAPACITOR MC10P×2 KC-30P</td> <td>68PF 270PF 470PF 0.01μF 5PF UJ 10PF UJ 20PF UJ 82PF NP</td>	100 Ω 330 Ω 100KΩ 1MΩ 10KB 50KB 2PF 5PF 10PF 20PF 39PF 68PF 100PF 0.001μF 0.01μF	1306 1311 1307 1310 1308, 1 1314 1303 1304 1301 1305 1317 VC 1301 VC 1301 1302 L	1309, 1312, 1316 CE CERAM VARIABLE TRIMMER	50 W V 50 W V 50 W V RAMIC DISC 50 W V CRAMIC TC 500 W V 500 W V 500 W V 500 W V 1C FEED THRU ECK-L1H102PE CAPACITOR C512C CAPACITOR MC10P×2 KC-30P	68PF 270PF 470PF 0.01μF 5PF UJ 10PF UJ 20PF UJ 82PF NP

			VR POTENT	IOMETER	
			1501, 1502	SR-19R	470 ΩB
			C CAPACI	FOR	
				CERAMIC DISC	0.001 E
			1504	50 W V	0.001µF
			1507, 1509	50WV	0.01µF
				CLECTROLYTIC	10 5
			1506	16 W V	10µF
R	EG UNIT		1503	16 W V	100µF
PB PRINT	ED CIRCUIT BOA	RD	1508	16 W V	220µF
1469 (A~Z)	REG CIRCUIT B	OARD	1505	16 W V	470µF
1405 (11 1)			1501, 1502	25 W V	2200µF
Q TRAN	SISTOR				
1502, 1505	2SC372Y				
1503	2SC735Y				
1501, 1504	2SD313D				
D DIODE					
1501	Si Bridge	M4B-5			
1505	Zener	WZ-061			
1502		WZ-090			
1503		WZ-110			
1504	Thyristor	CW-01B			
R RESI	STOR				
	CARBON FILM				
1509	1⁄4 W	220 Ω			
1511	1/4 W	270 Ω			
1501	1/4 W	330 Ω			
1512	$\frac{1}{4}W$	470 Ω			
1505	1⁄4 W	560 Ω			
1502, 1503	1⁄4 W	680 Ω			
1508	$\frac{1}{4}$ W	$1 \mathrm{K} \Omega$			
1504	1⁄4 W	2.7K Ω			
1506, 1510	1⁄4 W	3.3K Ω			
	WIRE WOUND				
1507	1 W	0.4Ω			









